=> FIL REG FILE 'REGISTRY' ENTERED AT 17:06:18 ON 03 JAN 2011 USE IS SUBJECT TO THE TERMS OF YOUR STN CUSTOMER AGREEMENT. PLEASE SEE "HELP USAGETERMS" FOR DETAILS. COPYRIGHT (C) 2011 American Chemical Society (ACS) => D HIS NOFILE FILE 'HCA' ENTERED AT 12:30:07 ON 03 JAN 2011 E US2006-581005/APPS 1 SEA SPE=ON ABB=ON PLU=ON US2006-581005/AP L1E DE2003-10357315/APPS 1 SEA SPE=ON ABB=ON PLU=ON (DE2003-10357315/AP OR DE2003-10357 L2315/PRN) E WO2004-EP13312/APPS L3 1 SEA SPE=ON ABB=ON PLU=ON (WO2004-EP13312/AP OR WO2004-EP1331 2/PRN) 1 SEA SPE=ON ABB=ON PLU=ON (L1 OR L2 OR L3) L4SEL L4 RN FILE 'REGISTRY' ENTERED AT 12:31:11 ON 03 JAN 2011 L516 SEA SPE=ON ABB=ON PLU=ON (435293-93-9/BI OR 7439-98-7/BI OR FILE 'HCA' ENTERED AT 12:32:35 ON 03 JAN 2011 SEL L4 AU 164 SEA SPE=ON ABB=ON PLU=ON ("GERHARD, ANJA"/AU OR "STOESSEL, L6 PHILIPP"/AU OR "VESTWEBER, HORST"/AU) E MERCK/CO 46962 SEA SPE=ON ABB=ON PLU=ON (MERCK+ALL/CO,CS,PA OR "MERCK A L8 27359 SEA SPE=ON ABB=ON PLU=ON ("MERCK JAPAN LIMITED"+ALL/CO,CS,PA 49438 SEA SPE=ON ABB=ON PLU=ON (L7 OR L8) L9 FILE 'LREGISTRY' ENTERED AT 13:15:52 ON 03 JAN 2011 L10 STR L11 STR L10 L12 STR FILE 'REGISTRY' ENTERED AT 13:22:04 ON 03 JAN 2011 L13 50 SEA SSS SAM L11 OR L12 SCR 2016 OR 1729 OR 1730 OR 1816 OR 1542 L14 L15 50 SEA SSS SAM (L11 OR L12) AND L14 L16 1374383 SEA SPE=ON ABB=ON PLU=ON PMS/CI L17 O SEA SPE=ON ABB=ON PLU=ON L5 AND L16 L18 SCR 2043 L19 50 SEA SSS SAM (L11 OR L12) AND L14 NOT L18 FILE 'LREGISTRY' ENTERED AT 13:43:10 ON 03 JAN 2011 L20 STR L11 L21 STR L12 FILE 'REGISTRY' ENTERED AT 13:45:37 ON 03 JAN 2011 L22 SCR 2016 OR 1729 OR 1816 OR 1542 L23 50 SEA SSS SAM (L20 OR L21) AND L22 L24 50 SEA SSS SAM (L20 OR L21) AND L22 NOT L18 FILE 'HCA' ENTERED AT 15:27:54 ON 03 JAN 2011 L25 175876 SEA SPE=ON ABB=ON PLU=ON (ELECTROLUM!N? OR ORGANOLUM!N? OR

(ELECTRO OR ORGANO OR ORG#)(2A)LUM!N? OR LIGHT?(2A)(EMIT? OR EMISSION?) OR EL OR E(W)L OR L(W)E(W)D OR OLED)/BI,AB OR

LED/IT SET SMARTSEL ON L26 SEL PLU=ON L25 1-50000 RN: 8745 TERMS (SELECT ENDED BY USER) SET SMARTSEL OFF FILE 'REGISTRY' ENTERED AT 15:35:24 ON 03 JAN 2011 L27 TRA PLU=ON L25 1- RN : 50070 TERMS L28 50068 SEA SPE=ON ABB=ON PLU=ON L27 L29 TRA PLU=ON L25 11144- RN : 50556 TERMS 50556 SEA SPE=ON ABB=ON PLU=ON L29
TRA PLU=ON L25 21383- RN: 50376 TERMS L30 L31 L32 50376 SEA SPE=ON ABB=ON PLU=ON L31 L33 TRA PLU=ON L25 34524- RN : 50311 TERMS 50311 SEA SPE=ON ABB=ON PLU=ON L33 L34 L35 TRA PLU=ON L25 57727- RN : 50734 TERMS 50734 SEA SPE=ON ABB=ON PLU=ON L35 L36 L37 TRA PLU=ON L25 79851- RN: 50351 TERMS
L38 50351 SEA SPE=ON ABB=ON PLU=ON L37
L39 TRA PLU=ON TOTAL CONTROL TO THE CONTROL T L39 TRA PLU=ON L25 99464- RN : 50499 TERMS 50499 SEA SPE=ON ABB=ON PLU=ON L39 L40 L41TRA PLU=ON L25 112996- RN : 50264 TERMS L42 50264 SEA SPE=ON ABB=ON PLU=ON L41 L43 TRA PLU=ON L25 138292- RN : 31183 TERMS 31182 SEA SPE=ON ABB=ON PLU=ON L43 L44345027 SEA SPE=ON ABB=ON PLU=ON L28 OR L30 OR L32 OR L34 OR L36 OR L45 L38 OR L40 OR L42 OR L44 L46 50 SEA SUB=L45 SSS SAM (L20 OR L21) L47 39366 SEA SUB=L45 SSS FUL (L20 OR L21) SAV L47 CLA005/A FILE 'HCA' ENTERED AT 16:55:30 ON 03 JAN 2011 L48 3809942 SEA SPE=ON ABB=ON PLU=ON L47 22614 SEA SPE=ON ABB=ON PLU=ON L48 AND L25 L49 E ELECTROLUMINESCENT DEVICES/CT L50 95754 SEA SPE=ON ABB=ON PLU=ON "ELECTROLUMINESCENT DEVICES"+PFT/CT 11199 SEA SPE=ON ABB=ON PLU=ON L49 AND L50 L51 23882 SEA SPE=ON ABB=ON PLU=ON PHOSPHORES?
796 SEA SPE=ON ABB=ON PLU=ON L51 AND L52
2057 SEA SPE=ON ABB=ON PLU=ON HOLE (2A) BLOCK? L52 L53 L54 58 SEA SPE=ON ABB=ON PLU=ON L53 AND L54 L55 L56 4 SEA SPE=ON ABB=ON PLU=ON L55 AND (L6 OR L9) 54 SEA SPE=ON ABB=ON PLU=ON L55 NOT L56 10 SEA SPE=ON ABB=ON PLU=ON 1802-2003/PY,PRY,AY AND L57 L58 TRA PLU=ON L58 1- RN HIT: L59 16 TERMS FILE 'REGISTRY' ENTERED AT 16:58:46 ON 03 JAN 2011 L60 16 SEA SPE=ON ABB=ON PLU=ON L59

	FILE 'HCA'	ENTERED AT	17:00:31	ON 03 J	AN 2011	
L61	60	SEA SPE=ON	ABB=ON	PLU=ON	L47 (L) L54	
L62	2	SEA SPE=ON	ABB=ON	PLU=ON	L61 AND (L6 OR L9)	
L63	4	SEA SPE=ON	ABB=ON	PLU=ON	L62 OR L56	
L64	58	SEA SPE=ON	ABB=ON	PLU=ON	L61 NOT L63	
L65	22	SEA SPE=ON	ABB=ON	PLU=ON	1802-2003/PY,PRY,AY AND L64	
L66	31	SEA SPE=ON	ABB=ON	PLU=ON	L58 OR L65	
L67		TRA PLU=ON	L66 1- F	RN HIT :	48 TERMS	

FILE 'REGISTRY' ENTERED AT 17:04:08 ON 03 JAN 2011

L68 48 SEA SPE=ON ABB=ON PLU=ON L67

L69 32 SEA SPE=ON ABB=ON PLU=ON L68 NOT L60

FILE 'REGISTRY' ENTERED AT 17:06:18 ON 03 JAN 2011

=> D L47 QUE STAT L20 STR

VAR G1=3/6 VAR G2=O/S NODE ATTRIBUTES: DEFAULT MLEVEL IS ATOM DEFAULT ECLEVEL IS LIMITED

GRAPH ATTRIBUTES:
RING(S) ARE ISOLATED OR EMBEDDED
NUMBER OF NODES IS 6

STEREO ATTRIBUTES: NONE L21 STR

G1**-**G2

VAR G1=S/C VAR G2=O/S NODE ATTRIBUTES: DEFAULT MLEVEL IS ATOM DEFAULT ECLEVEL IS LIMITED

GRAPH ATTRIBUTES:

RING(S) ARE ISOLATED OR EMBEDDED NUMBER OF NODES IS 2

STEREO ATTRIBUTES: NONE

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		ORGANOLUM!N? OR (ELECTRO OR ORGANO OR ORG#)(2A)LUM!N? OR
		LIGHT?(2A)(EMIT? OR EMISSION?) OR EL OR E(W)L OR L(W)E(W)D OR
		OLED)/BI,AB OR LED/IT
L27		TRANSFER PLU=ON L25 1- RN: 50070 TERMS
L28	50068	SEA FILE=REGISTRY SPE=ON ABB=ON PLU=ON L27
L29		TRANSFER PLU=ON L25 11144- RN: 50556 TERMS
L30	50556	SEA FILE=REGISTRY SPE=ON ABB=ON PLU=ON L29
L31		TRANSFER PLU=ON L25 21383- RN: 50376 TERMS
L32	50376	SEA FILE=REGISTRY SPE=ON ABB=ON PLU=ON L31
L33		TRANSFER PLU=ON L25 34524- RN: 50311 TERMS
L34	50311	SEA FILE=REGISTRY SPE=ON ABB=ON PLU=ON L33
L35		TRANSFER PLU=ON L25 57727- RN: 50734 TERMS
L36	50734	SEA FILE=REGISTRY SPE=ON ABB=ON PLU=ON L35
L37		TRANSFER PLU=ON L25 79851- RN: 50351 TERMS
L38	50351	SEA FILE=REGISTRY SPE=ON ABB=ON PLU=ON L37

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L39
              TRANSFER PLU=ON L25 99464- RN : 50499 TERMS
L40
       50499 SEA FILE=REGISTRY SPE=ON ABB=ON PLU=ON L39
L41
              TRANSFER PLU=ON L25 112996- RN : 50264 TERMS
L42
       50264 SEA FILE=REGISTRY SPE=ON ABB=ON PLU=ON L41
              TRANSFER PLU=ON L25 138292- RN : 31183 TERMS
L43
        31182 SEA FILE=REGISTRY SPE=ON ABB=ON PLU=ON L43
L44
        345027 SEA FILE=REGISTRY SPE=ON ABB=ON PLU=ON L28 OR L30 OR L32 OR
L45
              L34 OR L36 OR L38 OR L40 OR L42 OR L44
L47
         39366 SEA FILE=REGISTRY SUB=L45 SSS FUL (L20 OR L21)
100.0% PROCESSED 167479 ITERATIONS ( 1 INCOMPLETE) 39366 ANSWERS
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SEARCH TIME: 00.00.01

=> FIL HCA

FILE 'HCA' ENTERED AT 17:06:32 ON 03 JAN 2011 USE IS SUBJECT TO THE TERMS OF YOUR STN CUSTOMER AGREEMENT. PLEASE SEE "HELP USAGETERMS" FOR DETAILS. COPYRIGHT (C) 2011 AMERICAN CHEMICAL SOCIETY (ACS)

=> D L63 1-4 IBIB ABS HITSTR HITIND RETABLE

L63 ANSWER 1 OF 4 HCA COPYRIGHT 2011 ACS on STN ACCESSION NUMBER: 152:592162 HCA Full-text

TITLE: Cyclic arylphosphonic acid derivatives as

supplementary materials for organic

electroluminescent devices

Stoessel, Philipp; Heil, Holger; Joosten, INVENTOR(S):

Dominik; Pflumm, Christof; Gerhard, Anja; Breuning, Esther; Parham, Amir Hossain

Merck Patent GmbH, Germany PATENT ASSIGNEE(S):

SOURCE: PCT Int. Appl., 101pp.

CODEN: PIXXD2

DOCUMENT TYPE: Patent LANGUAGE: German

FAMILY ACC. NUM. COUNT: 3

PATENT INFORMATION:

PATENT NO.					KIND DATE			APPLICATION NO.					DATE				
WO	WO 2010054730					_	2010	20100520 T			 009-:	EP74	 06		20091015		
	W:	ΑE,	AG,	AL,	AM,	AO,	ΑT,	ΑU,	ΑZ,	BA,	BB,	BG,	BH,	BR,	BW,	BY,	BZ,
		CA,	CH,	CL,	CN,	CO,	CR,	CU,	CZ,	DE,	DK,	DM,	DO,	DZ,	EC,	EE,	EG,
		ES,	FΙ,	GB,	GD,	GE,	GH,	GM,	GT,	HN,	HR,	HU,	ID,	IL,	IN,	IS,	JP,
		ΚE,	KG,	KM,	KN,	KP,	KR,	KΖ,	LA,	LC,	LK,	LR,	LS,	LT,	LU,	LY,	MA,
		MD,	ME,	MG,	MK,	MN,	MW,	MX,	MY,	MZ,	NA,	NG,	NΙ,	NO,	NZ,	OM,	PE,
		PG,	PH,	PL,	PT,	RO,	RS,	RU,	SC,	SD,	SE,	SG,	SK,	SL,	SM,	ST,	SV,
		SY,	ТJ,	TM,	TN,	TR,	TT,	TZ,	UA,	UG,	US,	UZ,	VC,	VN,	ZA,	ZM,	ZW
	RW:	ΑT,	BE,	BG,	CH,	CY,	CZ,	DE,	DK,	EE,	ES,	FI,	FR,	GB,	GR,	HR,	HU,
		ΙE,	IS,	ΙΤ,	LT,	LU,	LV,	MC,	MK,	MT,	NL,	NO,	PL,	PT,	RO,	SE,	SI,
		SK,	SM,	TR,	BF,	ВJ,	CF,	CG,	CI,	CM,	GA,	GN,	GQ,	GW,	ML,	MR,	NE,
		SN,	TD,	TG,	BW,	GH,	GM,	KE,	LS,	MW,	MZ,	NA,	SD,	SL,	SZ,	TZ,	UG,
		ZM,	ZW,	AM,	AZ,	BY,	KG,	KΖ,	MD,	RU,	ΤJ,	TM					
DE	1020	0805	6688		A1		2010	0512		DE 2	-800	1020	0805	6688	2	0081	111
KR	2010	1282	07		Α		2010	1207		KR 2	009-	5558	7		2	0090	622

PRIORITY APPLN. INFO.:

DE 2008-102008056688A 20081111 DE 2009-102009022858A 20090527 5

OTHER SOURCE(S): MARPAT 152:592162

AΒ Phosphorus heterocyclic compds., preferably diazaphosphole, oxazaphosphole oxides, sulfides [QZ2P(X)]nAr (1, Q = benzo, areno, hetareno, substituted 1,2ethenediyl, etc.; Z = imino, O, S; X = O, S, preferably X = O; Ar = C6-60aryl, arylene; n = 1-6, preferably n = 1-3), useful as matrix and/or supplementary materials for organic electroluminescent devices (OLEDs), preferably for blue- and green-emitting OLEDs, based on phosphorescent transition metal complexes, improving performance, efficiency and lifetime of the OLEDs, for making of emitting, electron-, exciton-, or hole-blocking layers, were prepared by heterocyclization of aromatic o-diamines, oaminophenols Q(AH)2 with phosphonic dichlorides Ar[P(X)Cl2]n, which, in turn were prepared from the corresponding arylphosphonic, arenediphosphonic and arenetriphosphonic acids. The prepared compds. were tested in model OLEDs by doping the emission and hole-blocking layers, showing increase of efficiency and lifetime of the devices. In an example, 2,2'-(1,4-phenylene)bis(5,6dimethyl-1,3-diphenyl[1,3,2]benzophosphole) P,P'-dioxide (1a, Q = 4,5dimethylbenzene-1,2-diyl, Z = NPh, X = O, n = 2, Ar = 1,4-C6H4) was prepared by heterocyclization of 4,5-dimethyl-N,N'-diphenyl-1,2- benzenediamine with 1,4-benzenediphosphonic tetrachloride, Cl2P(O)-1,4-C6H4P(O)Cl2. In another example, the compound 1a, as matrix material doped with 10% tris(3-methyl-2phenylpyridine)iridium for 30 nm-thick light-emitting layer, showed 57 cd/A efficiency at 1000 cd m-2 light d. and 560 h lifetime at 4000 cd m-2 light d., compared with 42 cd/A and 230 h for similar device using bis(9,9'spirobifluoren-2-yl)phenylphosphine oxide as matrix material.

IT 1205555-94-7

(preparation of cyclic arylphosphonic acid derivs., benzo[1,3,2]-diazaphosphole oxides as supplementary materials for organic electroluminescent devices)

RN 1205555-94-7 HCA

CN Methanone, bis([1,1':3',1'':3'',1''':3''',1''''-quinquephenyl]-5''-yl)(CA INDEX NAME)

IT 1227269-53-5P, 1,4-Benzenediphosphonic tetrachloride

(preparation of cyclic arylphosphonic acid derivs., benzo[1,3,2]-diazaphosphole oxides as supplementary materials for organic electroluminescent devices)

RN 1227269-53-5 HCA

CN Phosphonic dichloride, P,P'-1,4-phenylenebis- (CA INDEX NAME)

IT 77918-51-5P 1227269-76-2P 1227269-77-3P

(preparation of cyclic arylphosphonic acid derivs., benzo[1,3,2]-diazaphosphole oxides as supplementary materials for organic electroluminescent devices)

RN 77918-51-5 HCA

CN Phosphonic dichloride, P-[1,1'-biphenyl]-4-yl- (CA INDEX NAME)

RN 1227269-76-2 HCA

CN Phosphonic dichloride, P,P'-[1,1'-biphenyl]-3,3'-diylbis- (CA INDEX NAME)

RN 1227269-77-3 HCA

CN Phosphonic dichloride, P,P'-1,3-phenylenebis- (CA INDEX NAME)

IPCI C09K0011-06 [I,A]

IPCR C09K0011-06 [I,C]; C09K0011-06 [I,A]

CC 29-7 (Organometallic and Organometalloidal Compounds)

Section cross-reference(s): 73, 76

ST diazaphosphole oxazaphosphole oxide arylphosphonic deriv prepn matrix material OLED; phosphorus heterocyclic phosphonic diamide aryl prepn matrix material OLED; phosphonic deriv cyclic material OLED matrix hole blocking; heterocyclization

arom amine arylphosphonic dichloride diazaphosphole oxazaphosphole prepn

IT Diphosphonates

Phosphonates

(arylphosphonate derivs.; preparation of cyclic arylphosphonic acid derivs.,

benzo[1,3,2]-diazaphosphole oxides as supplementary materials for organic electroluminescent devices)

IT Electroluminescent devices

(blue-emitting; preparation of cyclic arylphosphonic acid derivs., benzo[1,3,2]-diazaphosphole oxides as supplementary materials for organic electroluminescent devices)

ΙT Amines (diamines, aromatic; preparation of cyclic arylphosphonic acid derivs., benzo[1,3,2]-diazaphosphole oxides as supplementary materials for organic electroluminescent devices) ΙT Electroluminescent devices (green-emitting; preparation of cyclic arylphosphonic acid derivs., benzo[1,3,2]-diazaphosphole oxides as supplementary materials for organic electroluminescent devices) ΙT Electrochemical cells (light-emitting; preparation of cyclic arylphosphonic acid derivs., benzo[1,3,2]-diazaphosphole oxides as supplementary materials for organic electroluminescent devices) ΙT Plasmon (organic plasmon emitting devices; preparation of cyclic arylphosphonic acid derivs., benzo[1,3,2]-diazaphosphole oxides as supplementary materials for organic electroluminescent devices) ΙT Field effect transistors Integrated circuits Optical detectors Semiconductor lasers Solar cells Thin film transistors (organic; preparation of cyclic arylphosphonic acid derivs., benzo[1,3,2]-diazaphosphole oxides as supplementary materials for organic electroluminescent devices) Heterocyclic compounds ΙT (phosphorus, 1,3,2-diazaphosphole 2-oxides; preparation of cyclic arylphosphonic acid derivs., benzo[1,3,2]-diazaphosphole oxides as supplementary materials for organic electroluminescent devices) ΙT Electrophotographic photoconductors (photoreceptors) Heterocyclization (preparation of cyclic arylphosphonic acid derivs., benzo[1,3,2]-diazaphosphole oxides as supplementary materials for organic electroluminescent devices) 13716-12-6, Tri-tert-butylphosphine 78271-46-2, Phosphonic 3375-31-3 ΤТ acid, 1,3-phenylenebis-(preparation of cyclic arylphosphonic acid derivs., benzo[1,3,2]-diazaphosphole oxides as supplementary materials for organic electroluminescent devices) 1227269-57-9P 1227269-58-0P 1227269-59-1P 1227269-60-4P ΙT 1227269-61-5P 1227269-62-6P 1227269-63-7P 1227269-79-5P (preparation of cyclic arylphosphonic acid derivs., benzo[1,3,2]-diazaphosphole oxides as supplementary materials for organic electroluminescent devices) 2085-33-8, Tris(8-quinolinolato)aluminum 25387-93-3, ΤТ (8-Quinolinolato)lithium 50926-11-9, Indium tin oxide 105598-27-4 123847-85-8, 1,1'-Biphenyl-4-4'-diamine, 58328-31-7 N,N'-di-1-naphthalenyl-N,N'-diphenyl- 126213-51-2, PEDOT 164724-35-0 359014-71-4 435294-03-4 515834-67-0 561064-11-7 613682-85-2 1205555-94-7 1206465-62-4 1207176-84-8 (preparation of cyclic arylphosphonic acid derivs., benzo[1,3,2]-diazaphosphole oxides as supplementary materials for organic electroluminescent devices) 62-53-3, Aniline, reactions 92-66-0 92-67-1, [1,1'-Biphenyl]-4-amine ΤТ 95-53-4, o-Toluidine, reactions 106-49-0, p-Toluidine, reactions 504-24-5, 4-Pyridinamine 534-85-0, 1,2-Benzenediamine, N-phenyl-583-53-9, 1,2-Dibromobenzene 880-68-2, Phosphonic acid, 1,4-phenylenebis- 3842-55-5 10498-56-3, 1,4-Benzenediphosphonous tetrachloride 24932-48-7 28394-83-4, 1,2-Benzenediamine,

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N,N'-diphenyl- 38613-89-7, Phosphonous dichloride, 1,1'-biphenyl-4-yl-
     77918-47-9, Phosphonic acid, 1,1'-biphenyl-4-yl- 82495-68-9,
     1,3-Benzenediphosphonous tetrachloride 108724-77-2, Phosphonic acid,
     1,1'-biphenyl-3,3'-diylbis- 1227269-78-4
        (preparation of cyclic arylphosphonic acid derivs.,
        benzo[1,3,2]-diazaphosphole oxides as supplementary materials for organic
       electroluminescent devices)
     64436-68-6P 253334-40-6P 773056-31-8P 956471-82-2P 1225231-00-4P
ΙT
     1227269-53-5P, 1,4-Benzenediphosphonic tetrachloride
     1227269-54-6P 1227269-55-7P 1227269-56-8P 1227269-73-9P
     1227269-80-8P 1227269-81-9P
        (preparation of cyclic arylphosphonic acid derivs.,
       benzo[1,3,2]-diazaphosphole oxides as supplementary materials for organic
       electroluminescent devices)
    77918-51-5P 1227269-64-8P 1227269-65-9P 1227269-66-0P
ΙT
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     1227269-72-8P 1227269-74-0P 1227269-75-1P 1227269-76-2P
     1227269-77-3P 1227269-82-0P 1227269-83-1P 1227269-84-2P
     1227269-85-3P
        (preparation of cyclic arylphosphonic acid derivs.,
       benzo[1,3,2]-diazaphosphole oxides as supplementary materials for organic
       electroluminescent devices)
RETABLE
   Referenced Author | Year | VOL | PG | Referenced Work
                                                           | Referenced
   (RAU) | (RPY) | (RVL) | (RPG) | (RWK) | File
Anchisi, C | 1979 | 16 | 1439 | JOURNAL OF HETEROCYC | HCA Anisimova | 1976 | 46 | 807 | JOURNAL OF GENERAL C |
Anisimova | 1976 | 46 | 1807 | JOURNAL OF GENERAL C|
Konica Minolta Holdings | 2007 | | | JP 2007329495 A | HCA
Lister, J | 1966 | | 11242 | JOURNAL OF THE CHEMI | HCA
                     |1995 |41 |889 |HETEROCYCLES |
Satoshi, O
L63 ANSWER 2 OF 4 HCA COPYRIGHT 2011 ACS on STN
ACCESSION NUMBER: 145:498536 HCA Full-text
                       Organic electronic devices and boronic acid and
TITLE:
                       boronic acid derivatives used therein
                       Stoessel, Philipp; Breuning, Esther;
INVENTOR(S):
                        Buesing, Arne; Parham, Amir; Heil, Holger;
                        Vestweber, Horst
                       Merck Patent G.m.b.H., Germany
PATENT ASSIGNEE(S):
SOURCE:
                       PCT Int. Appl., 159pp.
                        CODEN: PIXXD2
DOCUMENT TYPE:
                       Patent
LANGUAGE:
                        German
FAMILY ACC. NUM. COUNT: 1
PATENT INFORMATION:
    PATENT NO. KIND DATE APPLICATION NO. DATE
    WO 2006117052
                                          _____
                       ____
                       A1 20061109 WO 2006-EP3150 20060406
        W: AE, AG, AL, AM, AT, AU, AZ, BA, BB, BG, BR, BW, BY, BZ, CA, CH,
            CN, CO, CR, CU, CZ, DE, DK, DM, DZ, EC, EE, EG, ES, FI, GB, GD,
            GE, GH, GM, HR, HU, ID, IL, IN, IS, JP, KE, KG, KM, KN, KP, KR,
            KZ, LC, LK, LR, LS, LT, LU, LV, LY, MA, MD, MG, MK, MN, MW, MX,
            MZ, NA, NG, NI, NO, NZ, OM, PG, PH, PL, PT, RO, RU, SC, SD, SE,
            SG, SK, SL, SM, SY, TJ, TM, TN, TR, TT, TZ, UA, UG, US, UZ, VC,
            VN, YU, ZA, ZM, ZW
         RW: AT, BE, BG, CH, CY, CZ, DE, DK, EE, ES, FI, FR, GB, GR, HU, IE,
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IS, IT, LT, LU, LV, MC, NL, PL, PT, RO, SE, SI, SK, TR, BF, BJ, CF, CG, CI, CM, GA, GN, GQ, GW, ML, MR, NE, SN, TD, TG, BW, GH,

GM, KE, LS, MW, MZ, NA, SD, SL, SZ, TZ, UG, ZM, ZW, AM, AZ, BY, KG, KZ, MD, RU, TJ, TM EP 1888706 20080220 EP 2006-724095 Α1 R: AT, BE, BG, CH, CY, CZ, DE, DK, EE, ES, FI, FR, GB, GR, HU, IE, IS, IT, LI, LT, LU, LV, MC, NL, PL, PT, RO, SE, SI, SK, TR JP 2008541417 Τ 20081120 JP 2008-509318 US 20090134384 Α1 20090528 US 2007-912939 20071029 CN 101171320 Α 20080430 CN 2006-80015401 20071105 KR 2008012337 Α 20080211 KR 2007-7028263 20071203 PRIORITY APPLN. INFO.: EP 2005-9643 Α 20050503 WO 2006-EP3150 W 20060406

ASSIGNMENT HISTORY FOR US PATENT AVAILABLE IN LSUS DISPLAY FORMAT OTHER SOURCE(S): MARPAT 145:498536

Organic electronic devices (e.g., organic or polymer light- emitting diodes, AB organic field-effect transistors, organic integrated circuits, organic thinfilm transistors, organic light- amitting transistors, organic solar cells, organic field quenching devices, organic light-emitting cells, organic photoreceptors, and organic laser diodes) are described which comprise ≥ 1 organic film including ≥1 aromatic boronic acid or boronic acid derivative compound The compds. may serve as fluorescent or phosphoresent dopants, as hole-blocking materials, as hole-transporting materials, or as electrontransporting materials. Oligomeric, dendrimeric, and polymeric compds. of boronic acid or boronic acid derivative compds. are also described. Methods for synthesizing polymers including boronic acid. derivs. are described which entail polycondensation of aliphatic or aromatic bis(diols), bis(dithiols), bis(diamines), or similar higher substituted compds. with an aromatic bisboronic acid or higher boronic acid or by reaction of an aromatic compound that includes 2 hydroxy, thiol, or amino groups as well as a boronic acid group.

IT 914307-04-3P 914307-06-5P

(organic electronic devices and boronic acid and boronic acid derivs. used in them and production of polymers including boronic acid-containing groups)

RN 914307-04-3 HCA

CN Methanone, 9,9'-spirobi[9H-fluorene]-2,2'-diylbis[[4-(4,4,5,5-tetramethyl-1,3,2-dioxaborolan-2-yl)phenyl]- (9CI) (CA INDEX NAME)

RN 914307-06-5 HCA

CN Phosphine oxide, 9,9'-spirobi[9H-fluoren]-2-yl-9,9'-spirobi[9H-fluoren]-2'-yl[4-(4,4,5,5-tetramethyl-1,3,2-dioxaborolan-2-yl)phenyl]- (CA INDEX NAME)

IT 586-75-4 3762-25-2 25069-38-9,

Bis(4-bromophenyl)(4-formylphenyl)amine 119001-43-3

187595-15-9

(organic electronic devices and boronic acid and boronic acid derivs. used in them and production of polymers including boronic acid-containing groups)

RN 586-75-4 HCA

CN Benzoyl chloride, 4-bromo- (CA INDEX NAME)

RN 3762-25-2 HCA

CN Phosphonic acid, P-[(4-methylphenyl)methyl]-, diethyl ester (CA INDEX NAME)

RN 25069-38-9 HCA

CN Benzaldehyde, 4-[bis(4-bromophenyl)amino]- (CA INDEX NAME)

RN 119001-43-3 HCA CN Benzaldehyde, 4,4',4''-nitrilotris- (CA INDEX NAME)

RN 187595-15-9 HCA

CN Phosphonic acid, [bis(4-bromophenyl)methyl]-, diethyl ester (9CI) (CA INDEX NAME)

IT 914307-05-4P, 2,2'-Bis(4-bromobenzoyl)spiro-9,9'-bifluorene
914307-07-6P

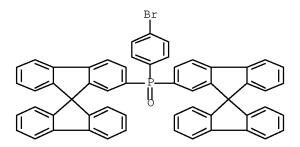
(organic electronic devices and boronic acid and boronic acid derivs. used in them and production of polymers including boronic acid-containing groups)

RN 914307-05-4 HCA

CN Methanone, 9,9'-spirobi[9H-fluorene]-2,2'-diylbis[(4-bromophenyl)- (9CI) (CA INDEX NAME)

RN 914307-07-6 HCA

CN Phosphine oxide, (4-bromophenyl)bis(9,9'-spirobi[9H-fluoren]-2-yl)- (9CI) (CA INDEX NAME)



IPCI C09K0011-06 [I,A]; H05B0033-14 [I,A]; C07F0005-02 [I,A]; C07F0005-05
[I,A]; C07F0005-00 [I,C*]; C07F0015-00 [I,A]

IPCR C09K0011-06 [I,C]; C09K0011-06 [I,A]; C07F0005-00 [I,C]; C07F0005-02
[I,A]; C07F0005-05 [I,A]; C07F0015-00 [I,C]; C07F0015-00 [I,A];
H05B0033-14 [I,C]; H05B0033-14 [I,A]

CC 76-3 (Electric Phenomena)

Section cross-reference(s): 52, 73, 74

ST electronic device boronic acid compd; fluorescent boronic acid compd; phosphorescent boronic acid compd; light emitting diode boronic acid compd; field effect transistor boronic

acid compd; integrated circuit boronic acid compd; thin film transistor boronic acid compd; light emitting transistor boronic

acid compd; solar cell boronic acid compd; field quenching device boronic acid compd; light emitting cell boronic acid compd;

photoreceptor boronic acid compd; laser diode boronic acid compd

IT Electrical materials

Fluorescent substances

Phosphorescent substances

Thin film transistors

(organic electronic devices and boronic acid and boronic acid derivs. used in them and production of polymers including boronic acid-containing groups)

IT Transistors

(organic light-emitting; organic electronic devices and boronic acid and boronic acid derivs. used in them and production of polymers including boronic acid-containing groups)

IT Electroluminescent devices

Electrophotographic photoconductors (photoreceptors)

Field effect transistors

Integrated circuits

Semiconductor devices

Semiconductor lasers

Solar cells

(organic; organic electronic devices and boronic acid and boronic acid derivs. used in them and production of polymers including boronic acid-containing groups)

910244-23-4P 914306-83-5P, 10-(4-Methylnaphth-1-yl)anthracen-9-boronic ΤТ acid pinacol ester 914306-84-6P 914306-85-7P 914306-86-8P 914306-88-0P 914306-90-4P 914306-91-5P 914306-94-8P 914306-95-9P 914306-98-2P 914306-96-0P 914306-97-1P 914307-03-2P 914307-04-3P 914307-06-5P 914307-08-7P 914307-09-8P 914307-11-2P

(organic electronic devices and boronic acid and boronic acid derivs. used in them and production of polymers including boronic acid-containing oups)

IT 64-19-7, Acetic acid, reactions 83-53-4, 1,4-Dibromonaphthalene

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84-65-1, Anthraquinone 90-11-9, 1-Bromonaphthalene 120-80-9,
    Pyrocatechol, reactions 121-43-7, Trimethyl borate 128-08-5,
    N-Bromosuccinimide 159-66-0, Spiro-9,9'-bifluorene 523-27-3,
    9,10-Dibromoanthracene 583-53-9, 1,2-Dibromobenzene 586-75-4
    611-24-5, 2-Methylaminophenol 620-93-9, Bis(4-methylphenyl)amine
    633-70-5, 2,6-Dibromoanthraquinone 918-21-8 1564-64-3,
    9-Bromoanthracene 3762-25-2 7726-95-6, Bromine, reactions
    15546-43-7, N,N',N'-Tetraphenylbenzidine 25015-63-8, Pinacolborane
    25069~38~9, Bis(4-bromophenyl)(4-formylphenyl)amine 58328-31-7
    85199-06-0, 2,5-Dimethylphenylboronic acid 100622-34-2, 9-Anthracene
    boronic acid 113040-41-8, Dibromopyrene 119001-43-3
    187595-15-9 454454-92-3 613682-84-1 914306-87-9
    914450-89-8
       (organic electronic devices and boronic acid and boronic acid derivs. used
       in them and production of polymers including boronic acid-containing
groups)
ΙT
    70430-42-1P 99372-95-9P 103986-53-4P 113664-24-7P,
    N, N, N', N'-Tetra(4-bromophenyl) benzidine 177799-11-0P 426218-39-5P,
    9,10-Bis(4-bromonaphth-1-yl)anthracene 560107-57-5P,
    1,2-Bis(anthracen-9-yl)benzene 597570-70-2P 663954-33-4P,
    1,6-Bis[(4-methylphenyl)amino]pyrene 756899-77-1P,
    1,4-Bis(anthracen-9-yl)naphthalene 910244-27-8P,
    1,2-Bis(10-bromoanthracen-9-yl)benzene 912483-18-2P 912483-19-3P
    914306-89-1P, 2,6-Dibromo-9,10-bis(naphth-1-yl)anthracene 914306-92-6P,
    1,6-Bis(2,5-dimethylphenyl)pyrene 914306-93-7P,
    1,6-Bis(2,5-dimethylphenyl)-3,8-dibromopyrene 914307-00-9P
    914307-02-1P 914307-05-4P,
    2,2'-Bis(4-bromobenzoyl)spiro-9,9'-bifluorene 914307-07-6P
    914307-10-1P, 1,6-Bis[(4-methylphenyl)amino]-3,8-dibromopyrene
    914307-12-3P, 9,10-Bis-N,N-[di(4-bromophenyl)amino]anthracene
       (organic electronic devices and boronic acid and boronic acid derivs. used
       in them and production of polymers including boronic acid-containing
groups)
RETABLE
  Referenced Author | Year | VOL | PG | Referenced Work | Referenced
  (RAU) | (RPY) | (RVL) | (RPG) | (RWK) | File
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Tirapattur, S
|2002 |124 |11576 |JOURNAL OF THE AMERI|HCA
Wong, K
                  |2000 |39 |4055 |ANGEWANDTE CHEMIE IN|HCA
Yamashita, M
                 4
OS.CITING REF COUNT:
                       THERE ARE 4 CAPLUS RECORDS THAT CITE THIS RECORD
                        (7 CITINGS)
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L63 ANSWER 3 OF 4 HCA COPYRIGHT 2011 ACS on STN ACCESSION NUMBER: 143:50534 HCA Full-text

TITLE: Organic electroluminescent element INVENTOR(S): Vestweber, Horst; Gerhard, Anja;

Stoessel, Philipp

PATENT ASSIGNEE(S): Covion Organic Semiconductors G.m.b.H.,

Germany

SOURCE: PCT Int. Appl., 28 pp.

CODEN: PIXXD2

DOCUMENT TYPE: Patent LANGUAGE: German

FAMILY ACC. NUM. COUNT: 1

PATENT INFORMATION:

P.	PATENT NO.					KIND DATE				APPLICATION NO.					DATE		
M.	2005	0544	03		 A1	_	2005	0616		 WO 2	004-	EP13.	312		2	0041	124
	W:	ΑE,	AG,	AL,	AM,	ΑT,	ΑU,	ΑZ,	BA,	BB,	BG,	BR,	BW,	BY,	BZ,	CA,	CH,
		CN,	CO,	CR,	CU,	CZ,	DE,	DK,	DM,	DZ,	EC,	EE,	EG,	ES,	FI,	GB,	GD,
		GE,	GH,	GM,	HR,	HU,	ID,	IL,	IN,	IS,	JP,	KE,	KG,	KP,	KR,	KΖ,	LC,
		LK,	LR,	LS,	LT,	LU,	LV,	MA,	MD,	MG,	MK,	MN,	MW,	MX,	MΖ,	NA,	NΙ,
		NO,	NZ,	OM,	PG,	PH,	PL,	PT,	RO,	RU,	SC,	SD,	SE,	SG,	SK,	SL,	SY,
		ΤJ,	TM,	TN,	TR,	TT,	TZ,	UA,	UG,	US,	UZ,	VC,	VN,	YU,	ZA,	ZM,	ZW
	RW:	BW,	GH,	GM,	ΚE,	LS,	MW,	MZ,	NA,	SD,	SL,	SZ,	TZ,	UG,	ZM,	ZW,	AM,
		AZ,	BY,	KG,	KΖ,	MD,	RU,	ТJ,	TM,	ΑT,	BE,	BG,	CH,	CY,	CZ,	DE,	DK,
		EE,	ES,	FI,	FR,	GB,	GR,	HU,	ΙE,	IS,	ΙΤ,	LU,	MC,	NL,	PL,	PT,	RO,
		SE,	SI,	SK,	TR,	BF,	ВJ,	CF,	CG,	CI,	CM,	GA,	GN,	GQ,	GW,	ML,	MR,
		ΝE,	SN,	TD,	ΤG												
D:	E 1035	7315			A1		2005	0707		DE 2	003-	1035	7315		2	0031	205
E	P 1697	483			A1		2006	0906		EP 2	004-	7980	62		2	0041	124
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							TR,	BG,	CZ,	EE,	HU,	PL,	SK,	IS			
C:	1894	358			А		2007	0110		CN 2	004-	8003	6011		2	0041	124
	P 2007						2007	0809		JP 2	006-	5418	41		2	0041	124
U	S 2007	0134	510		A1		2007	0614		US 2	006-	5810	05		2	0060	526
K	R 2006	1139	39		А		2006	1103		KR 2	006-	7010	957		2	0060	603
PRIORI	IY APP	LN.	INFO	.:						DE 2	003-	1035	7315	1	A 2	0031	205
A C C T C NT	WO 2004-EP13312 W 20041124																

ASSIGNMENT HISTORY FOR US PATENT AVAILABLE IN LSUS DISPLAY FORMAT OTHER SOURCE(S): MARPAT 143:50534

AB Organic electroluminescent devices comprising an anode, a cathode, ≥1 emitting layer, which consists of ≥1 matrix material which is doped with ≥1 phosphorescent emitter, and ≥1 hole-blocking layer are described which employ compds. including units described by the general formula Y:X (X has ≥1 nonbonded electron pair and is selected from NR, O, S, Se, or Te; R = C1-22 organic residue, OH, OR, NH2 NHR', and NR'2; R' = H or C1-20 organic residue;

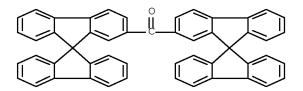
and Y = C, P, As, Sb, Bi, S, Se, or Te) as the hole -blocking material, the material being selected so that the hole-blocking and matrix materials are not identical. The use of the compds. in other electronic devices, including organic field-effect and thin-film transistors, organic integrated circuits, organic solar cells, or organic laser diodes is also described, as are the devices.

IT 782504-07-8 782504-10-3 824426-27-9

(devices with hole-blocking materials incorporating double bonded structural units)

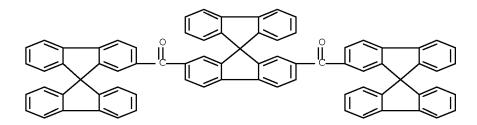
RN 782504-07-8 HCA

CN Methanone, bis(9,9'-spirobi[9H-fluoren]-2-y1)- (CA INDEX NAME)



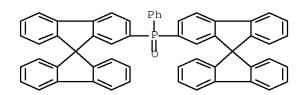
RN 782504-10-3 HCA

CN Methanone, 9,9'-spirobi[9H-fluorene]-2,7-diylbis[9,9'-spirobi[9H-fluoren]-2-yl-(9CI) (CA INDEX NAME)



RN 824426-27-9 HCA

CN Phosphine oxide, phenylbis(9,9'-spirobi[9H-fluoren]-2-y1)- (CA INDEX NAME)



IPCI C09K0011-06 [ICM,7]; H01L0051-30 [ICS,7]; H01L0051-05 [ICS,7,C*];
H05B0033-14 [ICS,7]; C07F0015-00 [ICS,7]

IPCR C07F0015-00 [I,C*]; C07F0015-00 [I,A]; C08G0061-00 [I,C*]; C08G0061-12
[I,A]; C09K0011-06 [I,C*]; C09K0011-06 [I,A]; H01L0051-00 [I,C*];
H01L0051-00 [I,A]; H01L0051-05 [I,C*]; H01L0051-30 [I,A]; H01L0051-50
[N,C*]; H01L0051-50 [N,A]; H05B0033-14 [I,C*]; H05B0033-14 [I,A]

CC 73-11 (Optical, Electron, and Mass Spectroscopy and Other Related

Properties)

Section cross-reference(s): 52, 76

thin film transistor hole blocking material double bonded unit; transistor hole blocking material double bonded unit; org electroluminescent device hole blocking material double bonded unit; semiconductor laser hole blocking material double bonded unit; solar cell hole blocking material double bonded unit; integrated circuit hole blocking material double bonded unit; FET hole blocking material double bonded unit; hole blocking material double bonded unit

Thin film transistors ΙT

> (devices with hole-blocking materials incorporating double bonded structural units)

ΤТ Imines

> Ketones, uses Phosphazenes

Phosphines

Sulfones

Sulfoxides

(devices with hole-blocking materials incorporating double bonded structural units)

ΙT Electroluminescent devices

Field effect transistors

Integrated circuits

Semiconductor lasers

Solar cells

(organic; devices with hole-blocking materials incorporating double bonded structural units)

782504-07-8 782504-10-3 824426-27-9 ΙT

> (devices with hole-blocking materials incorporating double bonded structural units)

7439-98-7D, Molybdenum, compds. 7440-04-2D, Osmium, compds. 7440-05-3D, Palladium, compds. 7440-06-4D, Platinum, compds.

7440-15-5D, Rhenium, compds. 7440-16-6D, Rhodium, compds. 7440-18-8D, Ruthenium, compds. 7440-22-4D, Silver, compds. 7440-33-7D, Tungsten,

7440-53-1D, Europium, compds. 7440-57-5D, Gold, compds.

94928-86-6, Tris(2-phenylpyridine)iridium 435293-93-9

(devices with hole-blocking materials incorporating

double bonded structural units)

RETABLE

TITLE:

Referenced Author		VOL PG	Referenced Work	Referenced
(RAU)		RVL) (RPG)	(RWK)	File
Anon	-+====+=: 1998 1	·	PATENT ABSTRACTS OF	
Konica Corporation	2003		EP 1353388 A	HCA
Oki Electric Ind Co Ltd	1 1998	1	JP 10231479 A	HCA
Salbeck, J	1997 9	1 209	SYNTHETIC METALS	HCA
Sato, H	2002		US 2002125818 A1	
Spreitzer, H	2000 4	105 125	PROCEEDINGS OF THE S	
Tokito, S	2000 3	63 290	THIN SOLID FILMS	
Watanabe, T	2002		US 2002015859 A1	HCA

L63 ANSWER 4 OF 4 HCA COPYRIGHT 2011 ACS on STN ACCESSION NUMBER: 143:34908 HCA Full-text

Organic electroluminescent element

hole-blocking layers with

six-membered ring unit-containing compounds and spirobifluorene derivatives and electronic devices using them

INVENTOR(S): Vestweber, Horst; Gerhard, Anja;

Stoessel, Philipp

PATENT ASSIGNEE(S): Covion Organic Semiconductors G.m.b.H.,

Germany

SOURCE: PCT Int. Appl., 38 pp.

CODEN: PIXXD2

DOCUMENT TYPE: Patent LANGUAGE: German

FAMILY ACC. NUM. COUNT: 1

PATENT INFORMATION:

PATENT NO.						KIND DATE		APPLICATION NO.						DATE			
WO	2005	0530	55		A1	_	2005	0609		WO 2	2004-:	EP13	 314		2	 0041	124
	W:	ΑE,	AG,	AL,	AM,	ΑT,	ΑU,	AZ,	BA,	BB,	, BG,	BR,	BW,	BY,	BZ,	CA,	CH,
		CN,	CO,	CR,	CU,	CZ,	DE,	DK,	DM,	DZ,	EC,	EE,	EG,	ES,	FI,	GB,	GD,
		GE,	GH,	GM,	HR,	HU,	ID,	IL,	IN,	IS,	, JP,	KΕ,	KG,	KP,	KR,	KΖ,	LC,
		LK,	LR,	LS,	LT,	LU,	LV,	MA,	MD,	MG,	, MK,	MN,	MW,	MX,	MZ,	NA,	NI,
		NO,	NΖ,	OM,	PG,	PH,	PL,	PT,	RO,	RU,	, SC,	SD,	SE,	SG,	SK,	SL,	SY,
		ТJ,	TM,	TN,	TR,	TT,	TZ,	UA,	UG,	US,	, UZ,	VC,	VN,	YU,	ZA,	ZM,	ZW
	RW:	BW,	GH,	GM,	KE,	LS,	MW,	MZ,	NΑ,	SD,	, SL,	SZ,	TZ,	UG,	ZM,	ZW,	ΑM,
		ΑZ,	BY,	KG,	KΖ,	MD,	RU,	ΤJ,	TM,	ΑT,	, BE,	BG,	CH,	CY,	CZ,	DE,	DK,
		EE,	ES,	FI,	FR,	GB,	GR,	HU,	ΙE,	IS,	IT,	LU,	MC,	NL,	PL,	PT,	RO,
		SE,	SI,	SK,	TR,	BF,	ВJ,	CF,	CG,	CI,	, CM,	GA,	GN,	GQ,	GW,	ML ,	MR,
		ΝE,	SN,	,													
DE	1035	6099			A1		2005	0707		DE 2	2003-	1035	6099		2	0031	127
	1687				A1		2006	0809		EP 2	2004-	8032	45		2	0041	124
EP	1687						2009										
	R:										, IT,				SE,	MC,	PT,
		,	SI,	FΙ,	,	CY,	,	,	,	,	, HU,	,	,				
	1954				A						2004-					0041	
	2007				_		2007				2006-					0041	
	4426				Τ						2004-					0041	
	2007				A1		2007				2006-				_	0060	
	2006				A		2006	1130			2006-				_	0060	
ORIT	Y APP	LN.	INFO	.:							2003-					0031	
										WO 2	2004-	EP13	314		W 2	0041	124

ASSIGNMENT HISTORY FOR US PATENT AVAILABLE IN LSUS DISPLAY FORMAT OTHER SOURCE(S): MARPAT 143:34908

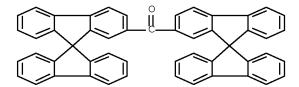
AB Organic electroluminescent devices comprising an anode, a cathode, and ≥1 emitting layer, which consists of a matrix material which is doped with ≥1 phosphorescent emitter, are described which employ compds. including units based on six-membered rings formed from C and/or N atoms, especially triazines, pyrimidines, pyridazines, and pyrazines, as materials for a hole-blocking layer between the emitting layer and the cathode. Compds., which may be employed in the devices, are described which comprise spirobifluorene derivs. with ≥1 triazine unit bonded to them, optionally along with other six-membered ring-containing substituents. The use of the design of the electroluminescent devices in other electronic devices, including organic transistors, organic integrated circuits, organic solar cells, organic laser diodes, or photoreceptors, is also described. Organic transistors, organic integrated circuits, organic laser diodes, or photoreceptors.

IT 782504-07-8

RN

(organic electroluminescent element with hole-blocking layers formed from compds. including six-membered rings and spirobifluorene derivs. and electronic devices using them) 782504-07-8 HCA

CN Methanone, bis(9,9'-spirobi[9H-fluoren]-2-yl)- (CA INDEX NAME)



IPCI H01L0051-30 [ICM, 7]; H01L0051-05 [ICM, 7, C*]; C07D0251-24 [ICS, 7]; C07D0251-00 [ICS,7,C*]; C07D0253-06 [ICS,7]; C07D0253-00 [ICS,7,C*]; C07D0239-26 [ICS, 7]; C07D0239-00 [ICS, 7, C*] IPCR C07D0239-00 [I,C*]; C07D0239-26 [I,A]; C07D0251-00 [I,C*]; C07D0251-24 [I,A]; C07D0253-00 [I,C*]; C07D0253-065 [I,A]; H01L0051-05 [I,C*]; H01L0051-30 [I,A] CC 73-11 (Optical, Electron, and Mass Spectroscopy and Other Related Properties) Section cross-reference(s): 25, 27, 28, 74, 76 spirobifluorene deriv hole blocking layer electronic ST device; transistor six membered ring deriv hole blocking layer; integrated circuit six membered ring deriv hole blocking layer; solar cell six membered ring deriv hole blocking layer; laser diode six membered ring deriv hole blocking layer; photoreceptor six membered ring deriv hole blocking layer; six membered ring deriv hole blocking layer electronic device; triazine deriv hole blocking layer org electroluminescent device; pyrimidine deriv hole blocking layer org electroluminescent device; pyrazine deriv hole blocking layer org electroluminescent device; pyridazine deriv hole blocking layer org electroluminescent device ΙT Imines Ketones, uses Phosphazenes Phosphines Sulfones Sulfoxides (emitting layer matrix; organic electroluminescent element with hole-blocking layers formed from compds. including six-membered rings and spirobifluorene derivs. and electronic devices using them) ΙT Spiro compounds (organic electroluminescent element with holeblocking layers formed from compds. including six-membered rings and spirobifluorene derivs. and electronic devices using them) ΙT Electroluminescent devices Electrophotographic photoconductors (photoreceptors) Integrated circuits Semiconductor lasers Solar cells Transistors (organic; organic electroluminescent element with holeblocking layers formed from compds. including six-membered rings and spirobifluorene derivs. and electronic devices using them) 7439-98-7D, Molybdenum, derivs. 7440-04-2D, Osmium, derivs.

7440-05-3D, Palladium, derivs. 7440-06-4D, Platinum, derivs.

7440-15-5D, Rhenium, derivs. 7440-16-6D, Rhodium, derivs. 7440-18-8D, Ruthenium, derivs. 7440-22-4D, Silver, derivs. 7440-33-7D, Tungsten, 7440-53-1D, Europium, derivs. 7440-57-5D, Gold, derivs. (emitting layer dopant; organic electroluminescent element with hole-blocking layers formed from compds. including six-membered rings and spirobifluorene derivs. and electronic devices using them) 289-80-5D, Pyridazine, derivs. 289-95-2D, Pyrimidine, derivs.

ΤТ

290-37-9D, Pyrazine, derivs. 782504-07-8

(organic electroluminescent element with hole-

blocking layers formed from compds. including six-membered

rings and spirobifluorene derivs. and electronic devices using them)

94928-86-6, Tris(2-phenylpyridine)iridium ΙT

(organic electroluminescent element with hole-

blocking layers formed from compds. including six-membered

rings and spirobifluorene derivs. and electronic devices using them)

ΙT 853154-59-3P 853154-60-6P 853154-61-7P

(organic electroluminescent element with hole-

blocking layers formed from compds. including six-membered

rings and spirobifluorene derivs. and electronic devices using them)

3842-55-5, 2-Chloro-4,6-diphenyl-1,3,5-triazine 34177-11-2, TТ

3-Chloro-5,6-diphenyl-1,2,4-triazine 463944-32-3 853154-62-8

(organic electroluminescent element with hole-

blocking layers formed from compds. including six-membered

rings and spirobifluorene derivs. and electronic devices using them)

RETABLE

Referenced Author (RAU)		VOL PG (RVL) (RPG)	Referenced Work (RWK)	Referenced File
	=+====+	====+=====	-+====================================	+=======
Anon	2003	2003	PATENT ABSTRACTS OF	1
Fink, R	2002		US 6352791 B1	HCA
Hayoz, P	2004		WO 2004077885 A	HCA
Hoechst Ag	1996		DE 4446818 A1	HCA
Hu, N	2001		US 6229012 B1	HCA
Jean-Hugues, F	2004	69 1762	JOURNAL OF ORGANIC C	
Nishi, T	2002		US 2002034659 A1	HCA
Toray Ind Inc	2003		JP 2003086381 A	HCA
Wu, C	2002	81 577	APPLIED PHYSICS LETT	HCA
Xerox Corporation	2004		EP 1385221 A	HCA
OS.CITING REF COUNT:	4	THERE ARE 4	4 CAPLUS RECORDS THAT	CITE THIS RECORD
		(9 CITINGS))	

=> D L66 1-31 IBIB ABS HITSTR HITIND RETABLE

L66 ANSWER 1 OF 31 HCA COPYRIGHT 2011 ACS on STN 143:376222 HCA Full-text ACCESSION NUMBER: TITLE: Organic light emitting diode

containing a novel Ir complex as a

phosphorescent emitter

INVENTOR(S): Cheng, Chien-Hong; Duan, Jiun-Pey; Rayabarapu, Dinesh

Kumar; Jennifer, Betty Marie

PATENT ASSIGNEE(S): Cheng, Chien-Hong, Taiwan SOURCE: U.S. Pat. Appl. Publ., 25 pp.

CODEN: USXXCO

DOCUMENT TYPE: Patent LANGUAGE: English

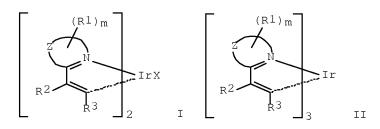
FAMILY ACC. NUM. COUNT: 2

PATENT INFORMATION:

PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
US 20050227109	A1	20051013	US 2004-822647	20040413 <
US 7320834	B2	20080122		
TW 232704	В	20050511	TW 2003-120288	20030724 <
KR 2005012132	A	20050131	KR 2004-55376	20040716 <
KR 853701	B1	20080825		
PRIORITY APPLN. INFO.:			TW 2003-120288 A	20030724 <
ASSIGNMENT HISTORY FOR U	S PATEN	T AVAILABLE	IN LSUS DISPLAY FORMAT	

OTHER SOURCE(S): MARPAT 143:376222

GΙ



AB Organic light-emitting diodes are described which employ an electroluminescent medium which comprises a phosphorescent Ir complex described by general formula I or II (X = a monoanionic bidentate ligand; Z = an atomic moiety capable of forming a nitrogen-containing heterocyclic group; R1 = H, halo, C1-6 alkyl, halogen-substituted C1-6 alkyl, C1-6 alkoxy, Ph-C1-6 alkyl, amino, and aryl; m = 0 or any pos. integer determined by the ring size of the nitrogen-containing heterocyclic group; R2 and R3 = independently selected H, halogen, C1-6 alkyl, halogen-substituted C1-6 alkyl, C1-6 alkoxy, Ph C1-6 alkyl, amino, aryl, and heterocyclic aryl).

1121-60-4, 2-Pyridinecarboxaldehyde 1122-62-9 10025-87-3, Phosphoryl chloride

(organic light-emitting diodes employing iridium complexes as phosphorescent emitters)

1121-60-4 HCA RN

CN 2-Pyridinecarboxaldehyde (CA INDEX NAME)

1122-62-9 HCA

Ethanone, 1-(2-pyridinyl)- (CA INDEX NAME) CN

RN 10025-87-3 HCA

CN Phosphoric trichloride (CA INDEX NAME)

INCL 428690000; X42-891.7; X31-350.4; X31-350.6; X25-710.2 IPCI H01L0051-54 [I,A]; H01L0051-50 [I,C*]; C09K0011-06 [N,A] IPCR H05B0033-14 [I,C*]; H05B0033-14 [I,A]; H01L0051-50 [I,C]; H01L0051-50 [I,A]; H01L0051-54 [I,A]; C09K0011-06 [I,C*]; C09K0011-06 [I,A]; H05B0033-12 [I,C*]; H05B0033-20 [I,A]; H05B0033-22 [I,C*]; H05B0033-22 [I,A] NCL 428/690.000; 257/102.000; 313/504.000; 313/506.000; 428/917.000; 257/E51.044 73-11 (Optical, Electron, and Mass Spectroscopy and Other Related CC Properties) Section cross-reference(s): 76, 78 ST org light emitting diode iridium complex phosphorescent emitter Phosphorescent substances ΙT (organic light-emitting diodes employing iridium complexes as phosphorescent emitters) Electroluminescent devices ΙT (organic; organic light-emitting diodes employing iridium complexes as phosphorescent emitters) 2085-33-8, Tris(8-hydroxyquinolinato)aluminum 123847-85-8, NPB TΤ 192198-85-9, TPBI (electron-transporting material; organic light-emitting diodes employing iridium complexes as phosphorescent emitters) 185690-41-9, 4,4',4''-Tris(2-naphthylphenylamino)triphenylamine ΙT (hole injection modification layer containing; organic lightemitting diodes employing iridium complexes as phosphorescent emitters) 4733-39-5, BCP ΙT 146162-54-1, BAlq (hole-blocking layer containing; organic lightemitting diodes employing iridium complexes as phosphorescent emitters) ΙT 19287-68-4 58328-31-7 (hole-transporting material; organic light-emitting diodes employing iridium complexes as phosphorescent emitters) 844818-66-2P ΤT 844818-67-3P 844818-68-4P 844818-69-5P 844818-70-8P 844818-71-9P 844818-72-0P 844818-73-1P 844818-74-2P 844818-75-3P (organic light-emitting diodes employing iridium complexes as phosphorescent emitters) 75-03-6, Ethyl iodide 100-39-0 109-04-6, 2-Bromopyridine 536-74-3, ΤТ Phenylacetylene 603-35-0, Triphenylphosphine, reactions 612-62-4 615-20-3 634-47-9 688-73-3, Tributyltin hydride 1121-60-4, 2-Pyridinecarboxaldehyde 1122-62-9 1532-72-5, Isoquinoline N-oxide 3510-66-5 10025-83-9, Iridium trichloride 10025-87-3 , Phosphoryl chloride 15727-65-8 52248-74-5 52334-81-3 59066-57-8, 1-((E)-2-Phenyl-1-ethenyl)isoquinoline (organic light-emitting diodes employing iridium

complexes as phosphorescent emitters)

IT 538-49-8P 4736-60-1P, Triphenylethylphosphonium iodide 7370-19-6P 13673-46-6P 19493-44-8P, 1-Chloroisoquinoline 38101-69-8P, 2-((E)-2-Phenyl-1-ethenyl)quinoline 53500-07-5P 59066-61-4P 66680-88-4P 84586-45-8P, 4-Methyl-2-((E)-2-phenyl-1-ethenyl)quinoline 844698-46-0P

(organic light-emitting diodes employing iridium complexes as phosphorescent emitters)

RETABLE

Referenced Author (RAU)	(RPY) (RVL) (- , , , ,	File
Deaton	=+====+= 2005	+	•
Deaton	2005	US 20050123798	
Hamada	2003	US 20030194580 <i> </i>	A1 HCA
Hamada	2006	US 7022422 B2	HCA
Lussier	2005	US 20050123795	A1 HCA
Sano	1995	US 5432014 A	HCA
Sato	2002	US 20020125818	A1 HCA
Takiguchi	2002	US 20020100906 A	A1 HCA
Takiguchi	2004	US 6797980 B2	HCA
Thompson	2002	US 20020034656 #	A1 HCA

L66 ANSWER 2 OF 31 HCA COPYRIGHT 2011 ACS on STN ACCESSION NUMBER: 142:490160 HCA Full-text TITLE: Light emitting devices and

materials for use in the devices

INVENTOR(S): Wudl, Fred; Mitsumori, Teruyuki; Sato, Yoshiharu;

Sato, Hideki; Shioya, Takeshi

PATENT ASSIGNEE(S): University of California, Los Angeles UCLA, USA;

Mitsubishi Chemical Corporation

SOURCE: PCT Int. Appl., 20 pp.

CODEN: PIXXD2

DOCUMENT TYPE: Patent LANGUAGE: English

FAMILY ACC. NUM. COUNT: 1

PATENT INFORMATION:

WO 2005048315 A2 20050526 WO 2004-US37843 20041110 WO 2005048315 A3 20060706 W: AE, AG, AL, AM, AT, AU, AZ, BA, BB, BG, BR, BW, BY, BZ, CA, CH, CN, CO, CR, CU, CZ, DE, DK, DM, DZ, EC, EE, EG, ES, FI, GB, GD,	PATENT I	KIN	KIND DATE			APPLICATION NO.					DATE						
W: AE, AG, AL, AM, AT, AU, AZ, BA, BB, BG, BR, BW, BY, BZ, CA, CH,	=								WO 2004-US37843					20041110 <			
GE, GH, GM, HR, HU, ID, IL, IN, IS, JP, KE, KG, KP, KR, KZ, LC, LK, LR, LS, LT, LU, LV, MA, MD, MG, MK, MN, MW, MX, MZ, NA, NI, NO, NZ, OM, PG, PH, PL, PT, RO, RU, SC, SD, SE, SG, SK, SL, SY, TJ, TM, TN, TR, TT, TZ, UA, UG, US, UZ, VC, VN, YU, ZA, ZM, ZW RW: BW, GH, GM, KE, LS, MW, MZ, NA, SD, SL, SZ, TZ, UG, ZM, ZW, AM, AZ, BY, KG, KZ, MD, RU, TJ, TM, AT, BE, BG, CH, CY, CZ, DE, DK, EE, ES, FI, FR, GB, GR, HU, IE, IS, IT, LU, MC, NL, PL, PT, RO, SE, SI, SK, TR, BF, BJ, CF, CG, CI, CM, GA, GN, GQ, GW, ML, MR,	₩:	AE, CN, GE, LK, NO, TJ, BW, AZ, EE,	E, A., C., A., C., C., C., C., C., C., C., C., C., C	G, AI O, CF GH, GM IR, LS IZ, OM CM, TN GH, GM SY, KG	AM, CU, I, HR, LT, PG, I, TR, KE, KZ, FR,	AT, CZ, HU, LU, PH, TT, LS, MD, GB,	AU, DE, ID, LV, PL, TZ, MW, RU, GR,	AZ, DK, IL, MA, PT, UA, MZ, TJ,	DM, IN, MD, RO, UG, NA, TM, IE,	DZ, IS, MG, RU, US, SD, AT, IS,	EC, JP, MK, SC, UZ, SL, BE, IT,	EE, KE, MN, SD, VC, SZ, BG, LU,	EG, KG, MW, SE, VN, TZ, CH, MC,	ES, KP, MX, SG, YU, UG, CY, NL,	FI, KR, MZ, SK, ZA, ZM, CZ, PL,	GB, KZ, NA, SL, ZM, ZW, DE,	GD, LC, NI, SY, ZW AM, DK, RO,

PRIORITY APPLN. INFO.:

US 2003-518986P P 20031110 <--

OTHER SOURCE(S): MARPAT 142:490160

AB Light-emitting materials represented by the general formula I,II,III and IV (Z1 = aromatic ring having a nitrogen atom; Z2 = fused ring; M = Ir,Pt or Pd) are described. An organic light-emitting device comprising the light-emitting layer is also described.

IT 533935-00-1

(hole injection material; light emitting devices and materials for use in devices)

RN 533935-00-1 HCA

CN Poly[oxy-1,4-phenylenecarbonyl-1,4-phenyleneoxy-1,4-phenylene(phenylimino)-1,4-phenylene(phenylimino)-1,4-phenylene] (CA INDEX NAME)

PAGE 1-B

IHCA

Anon

IPCI C07D0221-00 [I,C]; C07D0221-18 [I,A] IPCR C07D0221-00 [I,C]; C07D0221-18 [I,A]; C09K0011-06 [I,C*]; C09K0011-06 [I,A]; H01L [I,S]; H01L0051-00 [I,C*]; H01L0051-00 [I,A]; H01L0051-50 $[N,C^*]$; H01L0051-50 [N,A]; H05B0033-14 $[I,C^*]$; H05B0033-14 [I,A]CC 73-11 (Optical, Electron, and Mass Spectroscopy and Other Related Properties) Section cross-reference(s): 22, 76 ST light emitting material device LED ΤТ Electroluminescent devices Luminescent substances Phosphorescent substances (light emitting devices and materials for use in devices) 157077-25-3 ΙT (hole blocking material; light emitting devices and materials for use in devices) ΙT 1109-15-5 533935-00-1 (hole injection material; light emitting devices and materials for use in devices) IT 147-14-8, Copper phthalocyanine 2085-33-8, AlQ3 123847-85-8 811811-13-9 (light emitting devices and materials for use in devices) RETABLE Referenced Author | Year | VOL | PG | Referenced Work | Referenced $(RAU) \qquad |(RPY)|(RVL)|(RPG)| \qquad (RWK)$

L66 ANSWER 3 OF 31 HCA COPYRIGHT 2011 ACS on STN ACCESSION NUMBER: 142:363426 HCA Full-text

TITLE: Organic electroluminescent devices with high

luminance, durability, and emission efficiency and

materials therefor

INVENTOR(S): Onikubo, Shunichi; Enokida, Toshio; Suda, Yasumasa;

Toba, Yasumasa; Kimura, Yasunori; Kaneko, Tetsuya

PATENT ASSIGNEE(S): Toyo Ink Mfg. Co., Ltd., Japan SOURCE: Jpn. Kokai Tokkyo Koho, 35 pp.

CODEN: JKXXAF

DOCUMENT TYPE: Patent LANGUAGE: Japanese

FAMILY ACC. NUM. COUNT: 1

PATENT INFORMATION:

PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
JP 2005082703	A	20050331	JP 2003-316325	20030909 <
JP 4306379	B2	20090729		
PRIORITY APPLN. INFO.:			JP 2003-316325	20030909 <
OTHER SOURCE(S):	MARPAT	142:363426		
GI				

$$R^1$$
 X^2 R^2 R^2 R^2

The materials contain (A) heterocyclic compds. wherein plural N-containing rings are fused directly or via other carbon or heterocyclic rings and (B) phosphorescent substances (e.g., organic compds., Ir or Pt complexes with organic ligands). The compds. A may be I or II [X1, X2 = 0, S, NR3; R1-R3 = (cyclo)alkyl, aryl, heterocyclic]. In organic & devices having emitting layers or those-including plural organic layers between a pair of electrodes, ≥1 of the layers contain the above materials. The devices may have electron-injecting layers between the electron-injecting layers and the emitting layers, hole-blocking layers between the electron-injecting layers and the emitting layers, and/or hole-injecting layers between anodes and the emitting layers.

IT 4051-56-3 31671-77-9, Anthraldehyde

(in preparation of phosphors; phosphors containing benzobisthiazole-like fused

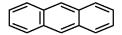
heterocyclic compds. for durable organic \mathbb{EL} devices with high emission efficiency)

RN 4051-56-3 HCA

CN Benzamide, N, N-diphenyl- (CA INDEX NAME)

RN 31671-77-9 HCA

CN Anthracenecarboxaldehyde (CA INDEX NAME)



D1- CHO

IPCI C09K0011-06 [I,A]; H01L0051-50 [I,A]

IPCR C09K0011-06 [I,A]; C09K0011-06 [I,C*]; H05B0033-14 [I,A]; H05B0033-14
[I,C*]; H01L0051-50 [I,C*]; H01L0051-50 [I,A]

CC 73-11 (Optical, Electron, and Mass Spectroscopy and Other Related Properties)

ST org electroluminescent emission efficiency durability luminance;
%%% phosphor benzobisthiazole benzobisoxazole benzobisimidazole;
phosphorescent iridium platinum complex doped %%%
phosphor

IT Electroluminescent devices

(organic; phosphors containing benzobisthiazole-like fused heterocyclic compds. for durable organic &L devices with high emission efficiency)

IT Phosphors

(phosphors containing benzobisthiazole-like fused heterocyclic compds. for durable organic $\Sigma\Sigma$ devices with high emission efficiency)

IT 14187-14-5 31248-39-2 94928-86-6 149005-33-4 343978-94-9 376367-93-0 848902-76-1

(dopants, emitting layers; phosphors containing benzobisthiazole-like fused heterocyclic compds. for durable organic %% devices with high emission efficiency)

IT 2085-33-8 395644-78-7

(electron-injecting layers; phosphors containing benzobisthiazole-like fused heterocyclic compds. for durable organic XI devices with high emission efficiency)

IT 65181-78-4

(emitting layers, hole-injecting layers; phosphors containing benzobisthiazole-like fused heterocyclic compds. for durable organic EL devices with high emission efficiency)

IT 905-62-4, 2,5-Bis(1-naphthyl)-1,3,4-oxadiazole (emitting layers; phosphors containing benzobisthiazole-like fused heterocyclic compds. for durable organic %% devices with high emission efficiency)

IT 219596-73-3P 219596-76-6P 219597-18-9P (emitting layers; phosphors containing benzobisthiazole-like fused heterocyclic compds. for durable organic %% devices with high emission efficiency)

IT 13399-13-8 133531-74-5 219596-84-6 219596-97-1 219597-01-0 219597-22-5 219597-29-2 219597-32-7 219597-58-7 848941-49-1 848941-50-4 848941-51-5 848941-52-6 848941-53-7 848941-54-8 (emitting layers; phosphors containing benzobisthiazole-like fused

heterocyclic compds. for durable organic $\Sigma\Sigma$ devices with high emission efficiency)

IT 1662-01-7, Bathophenanthroline 4733-39-5, Bathocuproin 146162-49-4 150405-69-9, 3-(4-Biphenylyl)-4-phenyl-5-(4-tert-butylphenyl)-1,2,4-triazole 188049-37-8 221554-51-4 848902-77-2 848902-78-3 (hole-blocking layers; phosphors containing

benzobisthiazole-like fused heterocyclic compds. for durable organic \mathtt{EL} devices with high emission efficiency)

IT 147-14-8, Copper phthalocyanine 123847-85-8 182507-83-1 185690-39-5, 4,4',4''-Tris[N-(1-naphthyl)-N-phenylamino]triphenylamine (hole-injecting layers; phosphors containing benzobisthiazole-like fused heterocyclic compds. for durable organic %% devices with high emission efficiency)

IT 4051-56-3 16523-31-2 31671-77-9, Anthraldehyde 848941-55-9

(in preparation of phosphors; phosphors containing benzobisthiazole-like fused $% \left(1\right) =\left(1\right) +\left(1\right) +\left($

heterocyclic compds. for durable organic $\Sigma\Sigma$ devices with high emission efficiency)

L66 ANSWER 4 OF 31 HCA COPYRIGHT 2011 ACS on STN ACCESSION NUMBER: 142:363425 HCA Full-text

TITLE: Organic electroluminescent devices with high

luminance, durability, and emission efficiency and

materials therefor

INVENTOR(S): Onikubo, Shunichi; Enokida, Toshio; Suda, Yasumasa;

Toba, Yasumasa; Kimura, Yasunori; Kaneko, Tetsuya

PATENT ASSIGNEE(S): Toyo Ink Mfg. Co., Ltd., Japan SOURCE: Jpn. Kokai Tokkyo Koho, 54 pp.

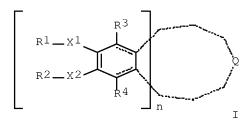
CODEN: JKXXAF

DOCUMENT TYPE: Patent LANGUAGE: Japanese

FAMILY ACC. NUM. COUNT: 1

PATENT INFORMATION:

PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
JP 2005082702	A	20050331	JP 2003-316324	20030909 <
PRIORITY APPLN. INFO.:			JP 2003-316324	20030909 <
OTHER SOURCE(S):	MARPAT	142:363425		
GI				



The materials contain compds. having I units [X1, X2 = 0, CO2, OCO; R1, R2 = (cyclo)alkyl, aryl, heterocyclic; R3, R4 = H, halo, CN, NO2, alkyl(oxy), aryl(oxy), alkylthio, arylthio, amino, acyl, heterocyclic; Q = fused ring structure or linking group forming rings with the units; n = 2-6] and phosphorescent substances (e.g., organic compds., Ir or Pt complexes with organic ligands). In organic EL devices having emitting layers (A) or A-including plural organic layers between a pair of electrodes, ≥1 of the layers contain the above materials. The devices may have hole-injecting layers (B) between anodes and A, electron-blocking layers between A and B, electron-injecting layers (C) between cathodes and A, and/or hole-blocking layers between C and A.

IT 32829-08-6 848940-24-9

(emitting layers; fused aromatic compound-containing phosphors for organic EL devices with high luminance, durability, and emission efficiency)

RN 32829-08-6 HCA

CN 2,3,6,7,10,11-Triphenylenehexol, 2,3,6,7,10,11-hexaacetate (CA INDEX NAME)

RN 848940-24-9 HCA

CN 5H-Tribenzo[a,f,k]trindene-2,3,7,8,12,13-hexacarboxylic acid, 10,15-dihydro-, 2,3,7,8,12,13-hexaphenyl ester (CA INDEX NAME)

IPCI C09K0011-06 [ICM,7]; H05B0033-14 [ICS,7]; H05B0033-22 [ICS,7]
IPCR C09K0011-06 [I,A]; C09K0011-06 [I,C*]; H05B0033-14 [I,A]; H05B0033-14
 [I,C*]; H05B0033-22 [I,A]; H05B0033-22 [I,C*]
CC 73-11 (Optical, Electron, and Mass Spectroscopy and Other Related

Properties)

ST org electroluminescent emission efficiency durability luminance; fused alkoxybenzene acyloxybenzene benzenecarboxylic acid EL phosphor; alkoxytriphenylene phosphor iridium platinum complex doped EL

IT Phosphors

(fused aromatic compound-containing phosphors for organic %% devices with high luminance, durability, and emission efficiency)

IT Electroluminescent devices

(organic; fused aromatic compound-containing phosphors for organic EL devices with high luminance, durability, and emission efficiency)

IT 14187-14-5 31248-39-2 94928-86-6 149005-33-4 344796-24-3 376367-93-0 848902-76-1

(dopants, emitting layers; fused aromatic compound-containing phosphors for organic

EL devices with high luminance, durability, and emission efficiency)

IT 208939-07-5 848940-26-1

(electron-blocking layers; fused aromatic compound-containing phosphors for organic

ML devices with high luminance, durability, and emission efficiency)

IT 2085-33-8 23467-27-8 395644-78-7

(electron-injecting layers; fused aromatic compound-containing phosphors for

organic ΣL devices with high luminance, durability, and emission efficiency)

IT 905-62-4, 2,5-Bis(1-naphthyl)1,3,4-oxadiazole 58328-31-7, CBP 65181-78-4 192198-85-9

(emitting layers; fused aromatic compound-containing phosphors for organic %% devices with high luminance, durability, and emission efficiency)

IT 23417-07-4 **32829-08-6** 32829-11-1 134025-08-4 134025-15-3

848940-23-8 **848940-24-9** 848940-25-0 848940-28-3

(emitting layers; fused aromatic compound-containing phosphors for organic EL devices with high luminance, durability, and emission efficiency)

IT 808-57-1P

ΙT

(fused aromatic compound-containing phosphors for organic EL devices with high luminance, durability, and emission efficiency)

IT 1662-01-7, Bathophenanthroline 4733-39-5, Bathocuproin 146162-49-4 146162-54-1 150405-69-9, 3-(4-Biphenylyl)-4-phenyl-5-(4-tert-butylphenyl)-1,2,4-triazole 221554-51-4 848902-77-2 848902-78-3

(hole-blocking layers; fused aromatic compound-containing phosphors for organic EL devices with high luminance,

durability, and emission efficiency) 208939-55-3 848940-21-6 848940-27-2

(hole-injecting and electron-blocking layers; fused aromatic compound-containing

phosphors for organic EL devices with high luminance, durability, and emission efficiency)

IT 147-14-8, Copper phthalocyanine 123847-85-8 182507-83-1 185690-39-5, 4,4',4''-Tris[N-(1-naphthyl)-N-phenylamino]triphenylamine

(hole-injecting layers; fused aromatic compound-containing phosphors for organic

 ΣL devices with high luminance, durability, and emission efficiency)

IT 91-16-7, 1,2-Dimethoxybenzene

(in preparation of phosphors; fused aromatic compound-containing phosphors for organic

EL devices with high luminance, durability, and emission efficiency)

OS.CITING REF COUNT: 1 THERE ARE 1 CAPLUS RECORDS THAT CITE THIS RECORD (1 CITINGS)

L66 ANSWER 5 OF 31 HCA COPYRIGHT 2011 ACS on STN ACCESSION NUMBER: 142:269139 HCA Full-text TITLE: Photoconductive imaging members

Wu, Jin; Tong, Yuhua; Lin, Liang-bih; Hu, Nan-xing; INVENTOR(S):

Ferrarese, Linda L.; Duff, James M.; Qi, Yu

Xerox Corporation, USA PATENT ASSIGNEE(S):

SOURCE: U.S. Pat. Appl. Publ., 10 pp.

CODEN: USXXCO

DOCUMENT TYPE: Patent LANGUAGE: English

FAMILY ACC. NUM. COUNT: 1

PATENT INFORMATION:

PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
US 20050042533	A1	20050224	US 2003-647055	20030822 <
US 6946226	B2	20050920		
CN 1584746	A	20050223	CN 2004-10057866	20040820 <
JP 2005070786	A	20050317	JP 2004-242148	20040823 <
JP 4541801	B2	20100908		
PRIORITY APPLN. INFO.:			US 2003-647055 A	20030822 <
ASSIGNMENT HISTORY FOR U	JS PATEN	IT AVAILABLE	IN LSUS DISPLAY FORMAT	

AS OTHER SOURCE(S): MARPAT 142:269139

A photoconductive imaging member comprised of a supporting substrate, a hole AR blocking layer thereover, a photogenerating layer, and a charge transport layer, and wherein the hole blocking layer is comprised of particles chemical attached on the surface of an electron transport component.

25038-59-9, PET, uses ΤТ

(hole blocking layer of electrophotog.

photoreceptor)

25038-59-9 HCA RN

Poly(oxy-1,2-ethanediyloxycarbonyl-1,4-phenylenecarbonyl) (CA INDEX NAME) CN

INCL 430064000; 430058800; 430059400; 430065000

IPCI G03G0005-14 [ICM, 7]

IPCR G03G0005-043 [I,C*]; G03G0005-047 [I,A]; G03G0005-05 [I,C*]; G03G0005-05 [I,A]; G03G0005-06 $[I,C^*]$; G03G0005-06 [I,A]; G03G0005-14 $[I,C^*]$; G03G0005-14 [I,A]

NCL 430/064.000; 430/058.800; 430/059.400; 430/065.000; 430/058.250

74-3 (Radiation Chemistry, Photochemistry, and Photographic and Other CC Reprographic Processes)

574-93-6D, Phthalocyanine, derivative 1344-28-1, Alumina, uses 7429-90-5, ΙT

Aluminum, uses 12679-43-5D, Naphthaquinone, derivative, carboxybenzyl 13463-67-7, Titania, uses 25038-59-9, PET, uses 61372-93-8 65181-78-4 93376-18-2 845784-80-7 845784-81-8

(hole blocking layer of electrophotog.

photoreceptor)

OS.CITING REF COUNT: 8 THERE ARE 8 CAPLUS RECORDS THAT CITE THIS RECORD (13 CITINGS)

L66 ANSWER 6 OF 31 HCA COPYRIGHT 2011 ACS on STN ACCESSION NUMBER: 142:165272 HCA Full-text
TITLE: Block copolymers for organic

electroluminescent (EL) device and

its display, illumination, and light source INVENTOR(S): Kawakami, Akira; Kita, Hiroshi; Ogino, Kenji

PATENT ASSIGNEE(S): Konica Minolta Holdings, Inc., Japan

SOURCE: Jpn. Kokai Tokkyo Koho, 56 pp.

CODEN: JKXXAF

DOCUMENT TYPE: Patent LANGUAGE: Japanese

FAMILY ACC. NUM. COUNT: 1

PATENT INFORMATION:

PATENT NO.	KIND	DATE	APPLICATION NO.	DATE	
JP 2005015508	A	20050120	JP 2003-177859	20030623 <	
JP 4300902	В2	20090722			
PRIORITY APPLN. INFO.:			JP 2003-177859	20030623 <	
GI					

AΒ The block copolymers comprise (A) block components of repeating units having hole-transporting units (HTU), (B) block components of repeating units having electron-transporting units (ETU), and (C) repeating units having phosphorescent units. Preferably, the block A is represented by the general formula [CHR1CR2(L1HTU1)]m1, I, or [O(CR3R4)11CR5(L3HTU3)]m3 (HTU1-HTU3 = hole-transporting moiety; R1-R5 = H, substituent; L1-L3 = linking group, bond; $m \ge 3$ integer; 11 = 1, 2, 3) and the block B is represented by the general formula [CHR6CR7(L4ETU1)]n1, II, or [O(CR8R9)12CR10(L6ETU3)]n3 (ETU1-ETU3 = electron-transporting moiety; R6-R10 = H, substituent; L4-L6 = linking group, bond; $n1-n3 \ge 3$ integer; 12 = 1, 2, 3). Preferably, the HTU comprise triphenylamine units and the ETU have F or F-containing substituents. Preferably, the surface free energy of the monomer forming HTU-containing repeating units is larger than that of the monomers of the ETU-containing repeating units and these monomers are incompatible to each other. Preferably, the block copolymers are prepared by atom.-transfer radical polymerization Preferably, ≥1 of the block A contains hydrolyzable silyl groups, more preferably, trialkoxysilyl groups, and also contains dialkylamino groups. organic ‰% device contains the A-B-C block copolymers in ≥1 of the organic

layers provided between a cathode and an anode. In another alternative, the organic EL device contains A-B block copolymers and phosphorescent compds. The organic EL device has high emission efficiency, long service life, and high productivity.

IT 830318-25-7P 830318-29-1P

(block copolymers for organic %% device for display, illumination, and light source)

RN 830318-25-7 HCA

CN Iridium, bis[3,5-difluoro-2-(2-pyridinyl-κN)phenyl-κC](4-ethenyl-2-pyridinecarboxylato-κN1,κO2)-, polymer with rel-4-[3-[3,5-bis(trifluoromethyl)phenyl]-5-(1-naphthalenyl)-4H-1,2,4-triazol-4-yl]phenyl (1R,2R,4R)-bicyclo[2.2.1]hept-5-ene-2-carboxylate and rel-4-(9H-carbazol-9-yl)phenyl (1R,2R,4R)-bicyclo[2.2.1]hept-5-ene-2-carboxylate, block (9CI) (CA INDEX NAME)

CM 1

CRN 830318-24-6 CMF C34 H23 F6 N3 O2

Relative stereochemistry.

CM 2

CRN 830318-23-5 CMF C26 H21 N O2

Relative stereochemistry.

$$\bigcap_{R} \bigcap_{Q} \bigcap_{Q$$

CM 3

CRN 830318-19-9 CMF C30 H18 F4 Ir N3 O2 CCI CCS

RN 830318-29-1 HCA
CN Bicyclo[2.2.1]hept-5-ene-2-carboxylic acid,
4-[3-[3,5-bis(trifluoromethyl)phenyl]-5-(1-naphthalenyl)-4H-1,2,4-triazol4-yl]phenyl ester, (1R,2R,4R)-rel-, polymer with
(1R,2R,4R)-rel-4-(9H-carbazol-9-yl)phenyl
bicyclo[2.2.1]hept-5-ene-2-carboxylate, block (9CI) (CA INDEX NAME)

CM 1

CRN 830318-24-6
CMF C34 H23 F6 N3 O2

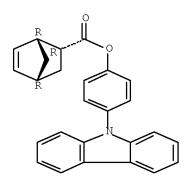
Relative stereochemistry.

$$F_3C$$
 N
 N
 N

CM 2

CRN 830318-23-5 CMF C26 H21 N O2

Relative stereochemistry.



IPCI C08F0297-00 [I,A]; C09K0011-06 [I,A]; H01L0051-50 [I,A] IPCR C08F0297-00 [I,A]; C08F0297-00 [I,C*]; C08G0065-00 [I,C*]; C08G0065-02 [I,A]; C09K0011-06 [I,A]; C09K0011-06 [I,C*]; H05B0033-14 [I,A]; H05B0033-14 [I,C*]; H05B0033-22 [I,A]; H05B0033-22 [I,C*]; H01L0051-50 [I,C*]; H01L0051-50 [I,A] CC 73-11 (Optical, Electron, and Mass Spectroscopy and Other Related Properties) Section cross-reference(s): 38, 74 ST hole transporting unit block copolymer electroluminescent device; electron transporting unit block copolymer electroluminescent device; phosphorescent unit block copolymer electroluminescent device; light source org electroluminescent device; illumination org electroluminescent device; org electroluminescent display block copolymer ΙT Light sources (block copolymers for organic ML device for display, illumination, and light source) ΙT Electroluminescent devices (displays; block copolymers for organic %% device for display, illumination, and light source) ΙT Luminescent screens (electroluminescent; block copolymers for organic EL device for display, illumination, and light source) ΙT (fluorescent; block copolymers for organic %% device for display, illumination, and light source) ΤТ Electroluminescent devices (organic; block copolymers for organic %% device for display, illumination, and light source) 828940-06-3P 830318-16-6P 830318-18-8P 830318-20-2P 830318-21-3P ΙT 830318-22-4P **830318-25-7P** 830318-26-8P 830318-27-9P 830318-28-0P **830318-29-1P** (block copolymers for organic EL device for display, illumination, and light source) 94928-86-6 344796-22-1 344796-24-3 376367-93-0 ΙT (phosphor; block copolymers for organic ™L device for display, illumination, and light source)

141:358036 HCA Full-text

Photoconductive imaging members with hole blocking

layer from oxide, phenolic compound and phenolic resin Wu, Jin; Hwang, Jennifer Y.; Lin, Liang-bih; Foley,

L66 ANSWER 7 OF 31 HCA COPYRIGHT 2011 ACS on STN

ACCESSION NUMBER:

TITLE:

INVENTOR(S):

Geoffrey M. t.; Wilbert, John J.

PATENT ASSIGNEE(S): Xerox Corporation, USA

SOURCE: U.S. Pat. Appl. Publ., 11 pp.

CODEN: USXXCO

DOCUMENT TYPE: Patent LANGUAGE: English

FAMILY ACC. NUM. COUNT: 1

PATENT INFORMATION:

PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
US 20040202947	A1	20041014	US 2003-410777	20030409 <
US 6967069	В2	20051122		

PRIORITY APPLN. INFO.: US 2003-410777 20030409 <--

ASSIGNMENT HISTORY FOR US PATENT AVAILABLE IN LSUS DISPLAY FORMAT

AB In a photoconductive imaging member including a hole blocking layer, a photogenerating layer, and a charge transport layer, the hole blocking layer contains, for example, a metal oxide dispersed in an in situ formed inorg./organic network. The inorg. component is preferably silica, titania or zirconia, and the organic component is a mixture of a phenolic compound and a phenolic resin, wherein the phenolic compound can contain, for example, at least two phenolic group. The SiO2, TiO2 or ZrO2 may be formed by hydrolysis of a precursor during curing of the hole blocking layer composition

IT 80-09-1, Bisphenol S 25085-75-0

(hole blocking layer dispersion containing; photoconductive imaging members with hole blocking layer from oxide, phenolic compound and phenolic resin)

RN 80-09-1 HCA

CN Phenol, 4,4'-sulfonylbis- (CA INDEX NAME)

RN 25085-75-0 HCA

CN Formaldehyde, polymer with 4,4'-(1-methylethylidene)bis[phenol] (CA INDEX NAME)

CM 1

CRN 80-05-7 CMF C15 H16 O2

$$\overset{\text{HO}}{\overbrace{\hspace{1.5cm}}}\overset{\text{Me}}{\underset{\text{Me}}{\overbrace{\hspace{1.5cm}}}}\circ \text{H}$$

CM 2

CRN 50-00-0

CMF C H2 O

H2C==O

INCL 430059400; 430065000; 430058800

IPCI G03G0005-14 [ICM, 7]

IPCR G03G0005-05 [I,C*]; G03G0005-05 [I,A]; G03G0005-14 [I,C*]; G03G0005-14 [T.A]

NCL 430/059.400; 430/058.800; 430/065.000; 430/131.000

 \mbox{CC} 74-3 (Radiation Chemistry, Photochemistry, and Photographic and Other Reprographic Processes)

Section cross-reference(s): 38

IT 80-09-1, Bisphenol S 123-31-9, 1,4-Benzenediol, uses 154-23-4, Catechin 1314-23-4, Zirconia, uses 1478-61-1, 4, 4'-(Hexafluoroisopropylidene)diphenol 7631-86-9, Silica, uses 9039-25-2, Cresol-formaldehyde-phenol copolymer 13463-67-7, Titania, uses 25085-75-0 28453-20-5,

Formaldehyde-p-tert.-butylphenol-phenol copolymer 68039-55-4, Ammonia-cresol-formaldehyde-phenol copolymer 741713-98-4, VARCUM 29159

(hole blocking layer dispersion containing; photoconductive imaging members with hole blocking

layer from oxide, phenolic compound and phenolic resin)

RETABLE

Referenced Author (RAU)	Year (RPY)	VOL PG (RVL) (RPG)	Referenced Work (RWK)	Referenced File
Anon	1988	 	JP 63-284560	HCA
Itoh	2003		US 20030099889 A1	HCA
Keoshkerian	1996		US 5482811 A	HCA
Listigovers	1996		US 5521043 A	HCA
Mayo	1995	1	US 5473064 A	HCA
Murti	2000		US 6015645 A	HCA
Ong	2001		US 6287737 B1	HCA
Stolka	1981	1	US 4265990 A	HCA
Wu Jin	2003	1	US 10369816	1
Yuh	2001	1	US 6261729 B1	HCA
OS.CITING REF COUNT:	4	THERE ARE	4 CAPLUS RECORDS THA	I CITE THIS RECORD
		(4 CITINGS)	

L66 ANSWER 8 OF 31 HCA COPYRIGHT 2011 ACS on STN ACCESSION NUMBER: 141:215563 HCA Full-text

TITLE: Electrophotographic photoconductor for copying and

printing with excellent photoinduced discharge characteristics, cyclic and environmental stability

INVENTOR(S): Wu, Jin; Lin, Liang-Bih; Hwang, Jennifer Y.

PATENT ASSIGNEE(S): Xerox Corporation, USA

SOURCE: U.S. Pat. Appl. Publ., 11 pp.

CODEN: USXXCO

DOCUMENT TYPE: Patent LANGUAGE: English

FAMILY ACC. NUM. COUNT: 1

PATENT INFORMATION:

PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
US 20040161684	A1	20040819	US 2003-369816	20030219 <
US 6913863	В2	20050705		

JP	2004252460	A	20040909	JΡ	2004-42366		20040219 <	
JP	4263637	B2	20090513					
US	20050186493	A1	20050825	US	2005-90532		20050325 <	
US	7001700	B2	20060221					
PRIORITY	APPLN. INFO.:			US	2003-369816	Α	20030219 <	

ASSIGNMENT HISTORY FOR US PATENT AVAILABLE IN LSUS DISPLAY FORMAT OTHER SOURCE(S): MARPAT 141:215563

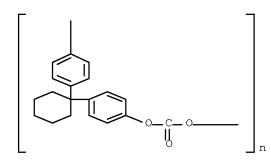
AB Electrophotog. photoconductor is described that has excellent photoinduced discharge characteristics, cyclic and environmental stability and acceptable charge deficient spot levels arising from dark injection of charge carriers. The photoconductor includes a mech. robust and solvent resistant polymeric hole blocking layer, a photogenerating layer, and a charge transport layer. The hole blocking layer that cures rapidly during fabrication and prevents or minimizes dark injection contains phenolic binders. Thus, the hole blocking layer contains a metal oxide and a phenolic compound/ phenolic resin blend, or a low. mol. weight phenolic resin/phenolic resin blend.

IT 25135-52-8, PCZ-400

(charge-transport layer binder; electrophotog. photoconductor hole blocking layer containing metal oxide and phenolic compound/ phenolic resin blend or blend of phenolic resins)

RN 25135-52-8 HCA

CN Poly(oxycarbonyloxy-1,4-phenylenecyclohexylidene-1,4-phenylene) (CA INDEX NAME)



IT 80-09-1, Bisphenol S

(hole blocking layer; electrophotog. photoconductor hole blocking layer containing metal oxide and phenolic compound/ phenolic resin blend or blend of phenolic resins)

RN 80-09-1 HCA

CN Phenol, 4,4'-sulfonylbis- (CA INDEX NAME)

$$\mathbb{H} \circ \mathbb{Q} = \mathbb{Q} \circ \mathbb{H}$$

IT 9005-09-8, VMCH

(photogenerating layer binder; electrophotog. photoconductor hole blocking layer containing metal oxide and phenolic compound/ phenolic resin blend or blend of phenolic resins)

RN 9005-09-8 HCA

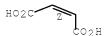
CN 2-Butenedioic acid (2Z)-, polymer with chloroethene and ethenyl acetate

(CA INDEX NAME)

CM 1

CRN 110-16-7 CMF C4 H4 O4

Double bond geometry as shown.



CM 2

CRN 108-05-4 CMF C4 H6 O2

AcO-CH-CH₂

CM 3

CRN 75-01-4 CMF C2 H3 C1

H2C ___ CH__C1

IT 25038-59-9, Poly(ethylene terephthalate), uses
(substrate; electrophotog. photoconductor having excellent photoinduced discharge characteristics and cyclic stability containing hole blocking layer with phenolic binders)

RN 25038-59-9 HCA

CN Poly(oxy-1,2-ethanediyloxycarbonyl-1,4-phenylenecarbonyl) (CA INDEX NAME)

INCL 430065000; 430058800; 430059400; 430059500; 430059100

IPCI G03G0005-14 [ICM, 7]

IPCR G03G0005-10 [I,C*]; G03G0005-10 [I,A]; G03G0005-14 [I,C*]; G03G0005-14
 [I,A]

NCL 430/065.000; 430/058.800; 430/059.100; 430/059.400; 430/059.500; 430/123.400; 430/123.430; 430/131.000

CC 74-3 (Radiation Chemistry, Photochemistry, and Photographic and Other Reprographic Processes)

IT 25135-52-8, PCZ-400

(charge-transport layer binder; electrophotog. photoconductor
hole blocking layer containing metal oxide and phenolic
compound/ phenolic resin blend or blend of phenolic resins)

IT 80-05-7, 4,4'-Isopropylidenediphenol, uses 80-09-1, Bisphenol S 108-46-3, 1,3-Benzenediol, uses 620-92-8, Bis(4-hydroxyphenyl)methane 843-55-0, Bisphenol Z 1478-61-1, 4,4'-(Hexafluoroisopropylidene)diphenol 2081-08-5, 4,4'-Ethylidenediphenol 2167-51-3, Bisphenol P 7631-86-9, Silica, uses 13392-26-2 13595-25-0, Bisphenol M 741713-98-4, Varcum 29159

(hole blocking layer; electrophotog. photoconductor hole blocking layer containing metal oxide and phenolic compound/ phenolic resin blend or blend of phenolic resins)

IT 9005-09-8, VMCH

(photogenerating layer binder; electrophotog. photoconductor hole blocking layer containing metal oxide and phenolic compound/ phenolic resin blend or blend of phenolic resins)

IT 25038-59-9, Poly(ethylene terephthalate), uses

(substrate; electrophotog. photoconductor having excellent photoinduced discharge characteristics and cyclic stability containing hole blocking layer with phenolic binders)

RETABLE

Referenced Author (RAU)	Year (RPY)	VOL PG (RVL) (RPG)	Referenced Work (RWK)	Referenced File
Anon	+ 1988	 	-+ JP 63284560 A	HCA
Diamond	2002	174	Handbook of Imaging	
Hor	1985		US 4555463 A	HCA
Hor	1986		US 4587189 A	HCA
Keoshkerian	1996		US 5482811 A	HCA
Listigovers	1996		US 5521043 A	HCA
Mayo	1995		US 5473064 A	HCA
Murti	2000		US 6015645 A	HCA
Nogami	1996		US 5561022 A	HCA
Ong	2001		US 6287737 B1	HCA
Stolka	1981		US 4265990 A	HCA
Wehelie	2000		US 6156468 A	CAPLUS
Wehelie	2001		US 6255027 B1	
Yashiki	1986		US 4579801 A	HCA
Yuh	1990		US 4921769 A	HCA
Yuh	2001		US 6177219 B1	HCA
OS.CITING REF COUNT:	46	THERE ARE	46 CAPLUS RECORDS THAT	CITE THIS
		RECORD (48	CITINGS)	

RECORD (48 CITINGS)

L66 ANSWER 9 OF 31 HCA COPYRIGHT 2011 ACS on STN ACCESSION NUMBER: 141:182064 HCA Full-text

TITLE: Organic electroluminescent device showing stable

operation for flat panel display

INVENTOR(S): Yoneyama, Tomio; Sato, Itsuki; Sato, Hideki

PATENT ASSIGNEE(S): Mitsubishi Chemical Corp., Japan SOURCE: Jpn. Kokai Tokkyo Koho, 38 pp. CODEN: JKXXAF

DOCUMENT TYPE: Patent LANGUAGE: Japanese

FAMILY ACC. NUM. COUNT: 1

PATENT INFORMATION:

PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
JP 2004220931	 А	20040805	JP 2003-7300	20030115 <
JP 4325197	В2	20090902		
PRIORITY APPLN. INFO.:			JP 2003-7300	20030115 <
OTHER SOURCE(S):	MARPAT	141:182064		
GT				

$$(z)_n$$

AB The title electroluminescent device includes a compound represented by I (Z = divalent connection group; n = 0-5) in a pos. hole blocking layer. The

Ι

compds. were synthesized in the examples. IT $733038{-}89{-}6\mathrm{P}$

(preparation of pos. hole blocking material for organic electroluminescent device showing stable operation for flat panel display)

RN 733038-89-6 HCA

CN 9H-Carbazole, 9,9'-(sulfonyldi-4,1-phenylene)bis- (9CI) (CA INDEX NAME)

IT 80-08-0, Bis(4-aminophenyl)sulfone

(preparation of pos. hole blocking material for organic electroluminescent device showing stable operation for flat panel display)

RN 80-08-0 HCA

CN Benzenamine, 4,4'-sulfonylbis- (CA INDEX NAME)

IPCI H01L0051-50 [I,A]; C07D0403-10 [I,A]; C07D0403-12 [I,A]; C07D0403-00
[I,C*]; C07D0413-10 [I,A]; C07D0413-00 [I,C*]; C09K0011-06 [I,A]

IPCR C07D0403-00 [I,C*]; C07D0403-10 [I,A]; C07D0403-12 [I,A]; C07D0413-00
 [I,C*]; C07D0413-10 [I,A]; C09K0011-06 [I,A]; C09K0011-06 [I,C*];
 H05B0033-14 [I,A]; H05B0033-14 [I,C*]; H05B0033-22 [I,A]; H05B0033-22
 [I,C*]; H01L0051-50 [I,C]; H01L0051-50 [I,A]

CC 74-13 (Radiation Chemistry, Photochemistry, and Photographic and Other Reprographic Processes)

Section cross-reference(s): 73

TT 733038-87-4P 733038-89-6P 733038-91-0P (preparation of pos. hole blocking material for organic

electroluminescent device showing stable operation for flat panel display)

IT \$0-08-0, Bis(4-aminophenyl)sulfone 86-74-8, Carbazole 341-58-2, 4,4'-Diamino-2,2'-bis(trifluoromethyl)biphenyl 2425-95-8, 2,5-Bis(4-aminophenyl)-1,3,4-oxadiazole 7681-11-0, Potassium iodide, reactions

(preparation of pos. hole blocking material for organic electroluminescent device showing stable operation for flat panel display)

OS.CITING REF COUNT: 3 THERE ARE 3 CAPLUS RECORDS THAT CITE THIS RECORD (3 CITINGS)

L66 ANSWER 10 OF 31 HCA COPYRIGHT 2011 ACS on STN ACCESSION NUMBER: 141:147906 HCA Full-text Organic light emitting diode

device with organic hole transporting material and

phosphorescent material

INVENTOR(S): Lee, Yung-Chih; Chen, Wei-Su; Liao, Chi-Chih; Lee,

Jiun-Haw

PATENT ASSIGNEE(S): Ritdisplay Corp., Taiwan SOURCE: U.S. Pat. Appl. Publ., 7 pp.

CODEN: USXXCO

DOCUMENT TYPE: Patent LANGUAGE: English

FAMILY ACC. NUM. COUNT: 1

PATENT INFORMATION:

PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
US 20040144974	A1	20040729	US 2003-248553	20030129 <
US 6822257	B2	20041123		
PRIORITY APPLN. INFO.:			US 2003-248553	20030129 <

ASSIGNMENT HISTORY FOR US PATENT AVAILABLE IN LSUS DISPLAY FORMAT

AB An organic light emitting diode (OLED) device that comprises a substrate, an anode layer, a light-emitting layer, a hole blocking layer and a cathode layer. The anode layer is positioned over the substrate and the light-emitting layer is positioned over the light-emitting layer and the cathode layer is positioned over the light-emitting layer and the cathode layer is positioned over the hole blocking layer. The light-emitting layer is an organic material layer consisted of hole transporting material and phosphorescent material in the organic material layer is between 40% to 60% by weight

IT 52234-82-9, TAZ

(organic light emitting diode device with organic hole transporting material and phosphorescent material)

RN 52234-82-9 HCA

CN 1-Aziridinepropanoic acid, 1,1'-[2-[[3-(1-aziridinyl)-1-oxopropoxy]methyl]-

2-ethyl-1,3-propanediyl] ester (CA INDEX NAME)

```
INCL 257040000; 257082000; 257184000
IPCI H01L0035-24 [ICM, 7]; H01L0035-12 [ICM, 7, C*]; H01L0051-00 [ICS, 7];
     H01L0027-15 [ICS,7]; H01L0031-12 [ICS,7]
IPCR H01L0051-05 [N,C*]; H01L0051-30 [N,A]; H01L0051-50 [I,C*]; H01L0051-50
     [I,A]; H01L0051-00 [N,C*]; H01L0051-00 [N,A]
NCL 257/040.000; 257/082.000; 257/184.000; 257/079.000; 257/098.000;
     257/099.000; 257/102.000; 257/103.000
CC
    73-12 (Optical, Electron, and Mass Spectroscopy and Other Related
     Properties)
     Section cross-reference(s): 76
     org light emitting diode device hole transporting
ST
     phosphorescent material; OLED hole transporting
     phosphorescent material
ΙT
    Electroluminescent devices
    Hole (electron)
```

Phosphorescent substances
Phosphors

(organic light emitting diode device with organic hole transporting material and phosphorescent material)

IT 119-65-3D, Isoquinoline, iridium complexes 147-14-8, Copper phthalocyanine 841-73-6, BCP 2085-33-8 7429-90-5, Aluminum, uses 7439-88-5D, Iridium, isoquinoline complexes 7440-70-2, Calcium, uses 15082-28-7, PBD 37271-44-6 37275-76-6, Aluminum zinc oxide 50926-11-9, Indium tin oxide 52234-82-9, TAZ 65181-78-4, TPD 117944-65-7, Indium zinc oxide 123847-85-8, NPB 124729-98-2, m-MTDATA 146162-54-1, Balq 148896-39-3 192198-85-9, TPBI

(organic light emitting diode device with organic hole transporting material and phosphorescent material)

RETABLE

Referenced Author (RAU)	, , , , ,	PG (RPG)	Referenced Work (RWK)	Referenced File
Adachi	=+======= 2002	=+===== 	-+====================================	+======= HCA
Adachi	2003		US 6573651 B2	HCA
Baldo	2000		US 6097147 A	HCA
Bellmann	2003		US 20030068525 A1	HCA
Hsieh	2003		US 20030162299 A1	HCA
Kwong	2002		US 20020074935 A1	HCA
Li	2003		US 20030138657 A1	HCA
Mishima	2002		US 20020096995 A1	HCA
Mori	2004		US 20040028944 A1	HCA
Sato	2003		US 20030218418 A9	HCA

OS.CITING REF COUNT: 2 THERE ARE 2 CAPLUS RECORDS THAT CITE THIS RECORD (2 CITINGS)

L66 ANSWER 11 OF 31 HCA COPYRIGHT 2011 ACS on STN 140:189702 HCA Full-text ACCESSION NUMBER:

TITLE: Polynuclear metal complexes as phosphorescence

emitters in electroluminescent layer

arrangements

INVENTOR(S): Heuer, Helmut-Werner; Wehrmann, Rolf; Sautter, Armin

PATENT ASSIGNEE(S): Germany

U.S. Pat. Appl. Publ., 30 pp. SOURCE:

CODEN: USXXCO

DOCUMENT TYPE: Patent LANGUAGE: English

FAMILY ACC. NUM. COUNT: 1

PATENT INFORMATION:

	PAT	TENT	NO.			KINI)	DATE	1	Ž	APPI	LICA	TION	NO.		D.	ATE		
							_			-						_			
	US	2004	0026	663		A1		2004	0212	Ţ	US 2	2003-	-6358	42		2	0030	806	<
	EΡ	1394	171			A1		2004	0303	I	EP 2	2003-	-1703	1		2	0030	728	<
		R:	ΑT,	BE,	CH,	DE,	DK,	ES,	FR,	GB,	GR,	IT,	, LI,	LU,	NL,	SE,	MC,	PT,	
			ΙE,	SI,	LT,	LV,	FI,	, RO,	MK,	CY,	AL,	TR,	, BG,	CZ,	EE,	HU,	SK		
	CA	2436	658			A1		2004	0209	(CA 2	2003-	-2436	658		2	0030	806	<
	JΡ	2004	0756	81		Α		2004	0311	· ·	JP 2	2003-	-2064	77		2	0030	807	<
	KR	2004	0143	46		Α		2004	0214	I	KR 2	2003-	-5490	7		2	0030	808	<
PRIOR	CTI	APP	LN.	INFO	.:					I	DE 2	2002-	-1023	6538	Ž	A 2	0020	809	<
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ASSIC OTHER SOURCE(S): MARPAT 140:189702

- Polynuclear metal complexes of the general formula (LmMe-HL)n-XL, a process for their preparation and their use as phosphorescence emitters in electroluminescent layer arrangements are described, where Me is a transition metal, L is a bidentate chelate-forming ligand, HL is a bidentate chelateforming ligand which complexes the transition metal Me and is addnl. bonded to a linker XL, XL is an n-functional linker and is covalently bonded to nauxiliary ligands ${\rm HL}$, ${\rm n}$ is an integer from 2 to 6 and ${\rm m}$ is an integer from 1 to 3.
- ΙT 90-02-8, 2-Hydroxybenzaldehyde, reactions (polynuclear metal complexes, their preparation and use as phosphorescence emitters in electroluminescent layer arrangements)
- 90-02-8 HCA RN
- CN Benzaldehyde, 2-hydroxy- (CA INDEX NAME)

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INCL 252301160; 428690000; 556018000
IPCI C09K0011-06 [ICM,7]; C07F0001-00 [ICS,7]
IPCR H05B0033-10 [I,C*]; H05B0033-10 [I,A]; C07B0061-00 [I,C*]; C07B0061-00
     [I,A]; C07C0249-00 [I,C*]; C07C0249-02 [I,A]; C07C0251-00 [I,C*];
    C07C0251-24 [I,A]; C07D0213-00 [I,C*]; C07D0213-16 [I,A]; C07D0213-26
    [I,A]; C07D0409-00 [I,C*]; C07D0409-04 [I,A]; C07F0005-00 [I,C*];
    C07F0005-00 [I,A]; C07F0015-00 [I,C*]; C07F0015-00 [I,A]; C09K0011-06
    [I,C*]; C09K0011-06 [I,A]; H01L0051-00 [I,C*]; H01L0051-00 [I,A];
    H01L0051-05 [I,C*]; H01L0051-30 [I,A]; H01L0051-50 [I,C*]; H01L0051-50
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[I,A]

NCL 252/301.160; 428/690.000; 556/018.000

CC 73-5 (Optical, Electron, and Mass Spectroscopy and Other Related Properties)

Section cross-reference(s): 76, 78

ST polynuclear metal complex phosphorescence electroluminescent device

IT Amines, uses

(aromatic, hole-conducting layer; polynuclear metal complexes, their preparation and use as phosphorescence emitters in electroluminescent layer arrangements)

IT Amines, uses

(aryl, tertiary, polynuclear metal complex-doped; polynuclear metal complexes, their preparation and use as phosphorescence emitters in electroluminescent layer arrangements)

IT Luminescent substances

(electroluminescent; polynuclear metal complexes, their preparation and use as phosphorescence emitters in electroluminescent layer arrangements)

IT Polymers, uses

(polynuclear metal complex-doped; polynuclear metal complexes, their preparation and use as phosphorescence emitters in electroluminescent layer arrangements)

IT Electroluminescent devices

Phosphorescent substances

(polynuclear metal complexes, their preparation and use as phosphorescence emitters in electroluminescent layer arrangements)

IT Transition metal complexes

(polynuclear metal complexes, their preparation and use as phosphorescence emitters in electroluminescent layer arrangements)

IT Coordination compounds

(polynuclear; polynuclear metal complexes, their preparation and use as phosphorescence emitters in electroluminescent layer arrangements)

IT Conducting polymers

(polythiophenes, cationic, hole-injecting layer; polynuclear metal complexes, their preparation and use as phosphorescence emitters in electroluminescent layer arrangements)

IT 124-41-4, Sodium methanolate 497-19-8, Sodium carbonate (Na2CO3), uses 584-08-7, Potassium carbonate (K2CO3)

(base, polynuclear metal complex prepared using; polynuclear metal complexes, their preparation and use as phosphorescence emitters in electroluminescent layer arrangements)

IT 4733-39-5, 2,9-Dimethyl-4,7-diphenyl[1,10]phenanthroline 34777-53-2 150405-69-9, TAZ 399038-18-7

(hole-blocking layer; polynuclear metal complexes, their preparation and use as phosphorescence emitters in electroluminescent layer arrangements)

IT 188049-41-4

(hole-blocking or electron-transport layer; polynuclear metal complexes, their preparation and use as phosphorescence emitters in electroluminescent layer arrangements)

IT 15082-28-7, 2-(4-Biphenylyl)-5-(4-tert-butylphenyl)-1,3,4-oxadiazole 25067-59-8, Poly-N-vinylcarbazole 25190-62-9, Poly(1,4-phenylene) 58328-31-7 99627-56-2, Poly(9H-fluorene-2,7-diyl)

(polynuclear metal complex-doped; polynuclear metal complexes, their preparation and use as phosphorescence emitters in

electroluminescent layer arrangements)

IT 7439-88-5DP, Iridium, compds. 7440-06-4DP, Platinum, compds. (polynuclear metal complexes, their preparation and use as phosphorescence emitters in electroluminescent layer arrangements)

IT 67360-21-8P 116563-50-9P 658042-18-3P (polynuclear metal complexes, their preparation and use as phosphorescence emitters in electroluminescent layer arrangements)

IT 4434-23-5P 17911-94-3P 20425-75-6P 658042-16-1P 658042-17-2P 658043-91-5P 658043-92-6P 658043-93-7P 658043-94-8P 658043-95-9P (polynuclear metal complexes, their preparation and use as phosphorescence emitters in electroluminescent layer arrangements)

IT 90-02-8, 2-Hydroxybenzaldehyde, reactions 101-77-9 108-45-2, m-Phenylenediamine, reactions 646-25-3, 1,10-Decanediamine 2479-47-2 2783-17-7, 1,12-Diaminododecane 3377-24-0 4097-89-6 85642-05-3 118727-34-7, 1,3,5-Tris(4-aminophenyl)benzene 343978-72-3 417705-49-8 (polynuclear metal complexes, their preparation and use as phosphorescence emitters in electroluminescent layer arrangements)

OS.CITING REF COUNT: 1 THERE ARE 1 CAPLUS RECORDS THAT CITE THIS RECORD (1 CITINGS)

L66 ANSWER 12 OF 31 HCA COPYRIGHT 2011 ACS on STN ACCESSION NUMBER: 140:67611 HCA Full-text

TITLE: Direct current chargeable electrophotographic

photoreceptor with intermediate layer

INVENTOR(S): Tanabe, Tsuyoshi; Nakamura, Kazunari; Uesugi,

Hirotoshi

PATENT ASSIGNEE(S): Canon Inc., Japan

SOURCE: Jpn. Kokai Tokkyo Koho, 15 pp.

CODEN: JKXXAF

DOCUMENT TYPE: Patent LANGUAGE: Japanese

FAMILY ACC. NUM. COUNT: 1

PATENT INFORMATION:

PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
JP 2004004292	A	20040108	JP 2002-159720	20020531 <
PRIORITY APPLN. INFO.:			JP 2002-159720	20020531 <

- AB The d.c direct-charging photoreceptor without charge-removing process comprises an electroconductive support successively coated with an intermediate layer with hole-blocking property containing metal oxide, a charge-generating layer and a charge-transporting layer. The electrophotog. apparatus having d.c. charging roller and the above photoreceptor and without charge removing means is also claimed. Image deterioration caused by charging unevenness is prevented.
- IT 9003-35-4, Plyophen J 325

(d.c. chargeable electrophotog. photoreceptor having intermediate layer
with hole-blocking property)

RN 9003-35-4 HCA

CN Phenol, polymer with formaldehyde (CA INDEX NAME)

CM 1

CRN 108-95-2 CMF C6 H6 O



CM 2

CRN 50-00-0 CMF C H2 O

H2C==O

IPCI G03G0005-14 [ICM,7]; G03G0005-06 [ICS,7]; G03G0005-10 [ICS,7]; G03G0015-02
[ICS,7]

IPCR G03G0005-14 [I,C*]; G03G0005-14 [I,A]; G03G0005-06 [I,C*]; G03G0005-06
[I,A]; G03G0005-10 [I,C*]; G03G0005-10 [I,A]; G03G0015-02 [I,C*];
G03G0015-02 [I,A]

CC 74-3 (Radiation Chemistry, Photochemistry, and Photographic and Other Reprographic Processes)

IT 9003-35-4, Plyophen J 325

(d.c. chargeable electrophotog. photoreceptor having intermediate layer
with hole-blocking property)

L66 ANSWER 13 OF 31 HCA COPYRIGHT 2011 ACS on STN ACCESSION NUMBER: 138:245268 HCA Full-text TITLE: New class of hole-blocking

amorphous molecular materials and their application in blue-violet-emitting fluorescent and green-emitting

phosphorescent organic
electroluminescent devices

AUTHOR(S): Okumoto, Kenji; Shirota, Yasuhiko

CORPORATE SOURCE: Department of Applied Chemistry, Faculty of

Engineering, Osaka University, Yamadaoka, Suita,

Osaka, 565-0871, Japan

SOURCE: Chemistry of Materials (2003), 15(3),

699-707

CODEN: CMATEX; ISSN: 0897-4756

PUBLISHER: American Chemical Society

DOCUMENT TYPE: Journal LANGUAGE: English

A new class of hole-blocking amorphous mol. materials for use in organic electroluminescent (EL) devices were developed, which include 1,3,5-tri(4-biphenylyl)benzene, 1,3,5-tris(4-fluorobiphenyl-4'-yl)benzene (F-TBB), 1,3,5-tris(9,9-dimethylfluoren-2-yl)benzene, and 1,3,5-tris[4-(9,9-dimethylfluoren-2-yl)phenyl]benzene. They readily form stable amorphous glasses with well-defined glass-transition temps. and are characterized by relatively high oxidation potentials and large HOMO-LUMO energy gaps. The use of these materials as hole blockers enabled blue-violet emission from several emitting amorphous mol. materials with hole-transporting properties in organic EL devices. A multilayer organic EL device using N,N-bis(9,9-dimethylfluoren-2-yl)aniline (F2PA) as a blue-violet emitter, F-TBB as a hole blocker, and 4,4',4''-tris[3-methylphenyl(phenyl)amino]triphenylamine and tris(8-quinolinolato)aluminum as hole and electron transporters, resp., exhibited blue-violet emission peaking at 405 nm with a high external quantum efficiency

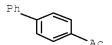
of 1.95%. This device also enabled the doping of a phosphorescent Ir complex, tris(2-phenylpyridine)iridium (Ir(ppy)3), tuning the emission color from blue violet to green by excitation energy transfer from F2PA to Ir(ppy)3.

IT 92-91-1, 4-Acetylbiphenyl

(synthesis of TBB; synthesis of organic hole-blocking amorphous mol. materials and application in fluorescent and phosphorescent organic electroluminescent devices)

RN 92-91-1 HCA

CN Ethanone, 1-[1,1'-biphenyl]-4-yl- (CA INDEX NAME)



CC 73-11 (Optical, Electron, and Mass Spectroscopy and Other Related Properties)

Section cross-reference(s): 22, 72, 76

ST amorphous hole blocking org material synthesis; fluorescent phosphorescent light emitting device

IT LUMO (molecular orbital)

(HOMO gap; of organic hole blocking and light -emitting materials)

IT HOMO (molecular orbital)

(LUMO gap; of organic hole blocking and light -emitting materials)

IT Electronic excitation

Fluorescence

(absorption and fluorescence maxima of organic hole blocking and light-emitting materials)

IT Oxidation potential

(half-wave; of organic hole blocking and light
-emitting materials)

IT Luminescence, electroluminescence

(of electroluminescent devices containing organic hole blocking and light-emitting materials)

IT Glass transition temperature

HOMO (molecular orbital)

LUMO (molecular orbital)

(of organic hole blocking and lightemitting materials)

IT Half wave potential

(oxidation; of organic hole blocking and light-emitting materials)

IT Electroluminescent devices

Hole (electron)

(synthesis of organic hole-blocking amorphous mol. materials and application in fluorescent and phosphorescent organic electroluminescent devices)

IT 50926-11-9, Indium tin oxide

(anode; synthesis of organic hole-blocking amorphous mol. materials and application in fluorescent and phosphorescent organic electroluminescent devices)

IT 37271-44-6

(cathode; synthesis of organic hole-blocking amorphous mol. materials and application in fluorescent and phosphorescent organic electroluminescent devices)

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ΙT
     6326-64-3P 372956-40-6P
                               441352-90-5P
                                                441352-91-6P
        (hole blocking material; synthesis of organic
        hole-blocking amorphous mol. materials and
        application in fluorescent and phosphorescent organic
        electroluminescent devices)
ΙT
     65181-78-4, TPD
        (light emitting material; synthesis of organic
        hole-blocking amorphous mol. materials and
        application in fluorescent and phosphorescent organic
        electroluminescent devices)
     134008-76-7P
                    165320-27-4P
                                  246857-02-3P
ΙT
        (light emitting material; synthesis of organic
        hole-blocking amorphous mol. materials and
        application in fluorescent and phosphorescent organic
        electroluminescent devices)
ΙT
     94928-86-6
        (phosphorescent organic electroluminescent device;
        synthesis of organic hole-blocking amorphous mol.
        materials and application in fluorescent and phosphorescent
        organic electroluminescent devices)
ΙT
     151417-38-8P, 1,3,5-Tris(4-iodophenyl)benzene
        (reactant for synthesis of F-TBB, TFPB; synthesis of organic hole
        -blocking amorphous mol. materials and application in
        fluorescent and phosphorescent organic
        electroluminescent devices)
     144981-85-1P, 9,9-Dimethyl-2-iodofluorene
ΙT
        (reactant for synthesis of F2PA; synthesis of organic hole-
        blocking amorphous mol. materials and application in
        fluorescent and phosphorescent organic
        electroluminescent devices)
     16218-28-3P, 2,7-Diiodofluorene
                                       355832-04-1P,
ΤТ
     N-(9,9-Dimethylfluoren-2-yl)aniline
        (reactant for synthesis of PFFA; synthesis of organic hole-
        blocking amorphous mol. materials and application in
        fluorescent and phosphorescent organic
        electroluminescent devices)
     612-71-5, 1,3,5-Triphenylbenzene
ΙT
        (synthesis of 1,3,5-tris(4-iodophenyl)benzene; synthesis of organic
        hole-blocking amorphous mol. materials and
        application in fluorescent and phosphorescent organic
        electroluminescent devices)
     7553-56-2, Iodine, reactions 10450-60-9, Periodic acid (H5IO6)
ΤT
        (synthesis of 2-iodofluorene, 2,7-diiodofluorene,
        1,3,5-tris(4-iodophenyl)benzene; synthesis of organic hole-
        blocking amorphous mol. materials and application in
        fluorescent and phosphorescent organic
        electroluminescent devices)
TТ
     86-73-7, Fluorene
        (synthesis of 2-iodofluorene, 2,7-diiodofluorene; synthesis of organic
        hole-blocking amorphous mol. materials and
        application in fluorescent and phosphorescent organic
        electroluminescent devices)
     74-88-4, Methyliodide, reactions
                                        865-47-4
ΤT
        (synthesis of 9,9-dimethyl-2-iodofluorene,
        9,9-dimethyl-2,7-diiodofluorene; synthesis of organic hole-
       blocking amorphous mol. materials and application in
        fluorescent and phosphorescent organic
        electroluminescent devices)
     2523-42-4P, 2-Iodofluorene
ΙT
        (synthesis of 9,9-dimethyl-2-iodofluorene,
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January 3, 2011 48

10/581,005 9,9-dimethyl-2,7-diiodofluorene; synthesis of organic holeblocking amorphous mol. materials and application in fluorescent and phosphorescent organic electroluminescent devices) ΙT 14221-01-3, Tetrakis(triphenylphosphine)palladium (synthesis of F-TBB, TFB, TFPB; synthesis of organic holeblocking amorphous mol. materials and application in fluorescent and phosphorescent organic electroluminescent devices) 1765-93-1, 4-Fluorophenylboronic acid (synthesis of F-TBB; synthesis of organic hole-blocking amorphous mol. materials and application in fluorescent and phosphorescent organic electroluminescent devices) 108-67-8, Mesitylene, uses ΙT (synthesis of F2PA, p-BPD, PFFA; synthesis of organic holeblocking amorphous mol. materials and application in fluorescent and phosphorescent organic electroluminescent devices) 7440-50-8, Copper, uses ΙT (synthesis of N-(9,9-Dimethylfluoren-2-yl) aniline, 1,3,5-tris(4-iodophenyl)benzene, PFFA; synthesis of organic hole -blocking amorphous mol. materials and application in fluorescent and phosphorescent organic electroluminescent devices) 62-53-3, Aniline, reactions ΙT (synthesis of N-(9,9-Dimethylfluoren-2-yl)aniline, F2PA; synthesis of organic hole-blocking amorphous mol. materials and application in fluorescent and phosphorescent organic electroluminescent devices) ΙT 144981-86-2P, 9,9-Dimethyl-2,7-diiodofluorene (synthesis of N-(9,9-Dimethylfluoren-2-yl) aniline; synthesis of organic hole-blocking amorphous mol. materials and application in fluorescent and phosphorescent organic electroluminescent devices) 92-91-1, 4-Acetylbiphenyl 1493-13-6 ΙΤ (synthesis of TBB; synthesis of organic hole-blocking amorphous mol. materials and application in fluorescent and phosphorescent organic electroluminescent devices) ΙT 333432-28-3 (synthesis of TFB, TFPB; synthesis of organic holeblocking amorphous mol. materials and application in fluorescent and phosphorescent organic electroluminescent devices) ΙT 626-39-1, 1,3,5-Tribromobenzene (synthesis of TFB; synthesis of organic hole-blocking amorphous mol. materials and application in fluorescent and phosphorescent organic electroluminescent devices) ΙT 2085-33-8, AlQ3 124729-98-2 (synthesis of organic hole-blocking amorphous mol. materials and application in fluorescent and phosphorescent organic electroluminescent devices)

ΙT 1591-31-7, 4-Iodobiphenyl 84161-87-5, N,N-Diphenylbenzidine (synthesis of p-BPD; synthesis of organic hole-blocking amorphous mol. materials and application in fluorescent and phosphorescent organic electroluminescent devices)

RETABLE

ΙT

Referenced Author	Year	VOL	PG	Referenced Work	Referenced
(RAU)	(RPY)	(RVL)	(RPG)	(RWK)	File
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January 5, 2011		10/3	81,003		
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Kinoshita, M	2001		614	Chem Lett	HCA
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Lamansky, S	2001	123	4304	J Am Chem Soc	HCA
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Ogawa, H	1997	91	243	Synth Met	HCA
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Okumoto, K	2001			Appl Phys Lett	HCA
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Robinson, M	2001	11	413	Adv Funct Mater	HCA
Romero, D	1997	19	1158	Adv Mater	HCA
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Shirota, Y	1994	65	1807	Appl Phys Lett	HCA
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Stolka, M	1984	88	4707	J Phys Chem	HCA
Tang, B	2001	11		J Mater Chem	HCA
Ueta, E	1994	1	2397	Chem Lett	HCA
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Yang, Y	1996	79	934	J Appl Phys	HCA
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OS.CITING REF COUNT:	68			8 CAPLUS RECORDS THAT	CITE THIS
				CITINGS)	

L66 ANSWER 14 OF 31 HCA COPYRIGHT 2011 ACS on STN ACCESSION NUMBER: 137:391797 HCA Full-text TITLE: High-efficiency organic electroluminescent devices using iridium complex emitter and arylamine-containing polymer buffer layer Fukase, Akio; Luan, Kinh; Dao, Thanh; Kido, Junji AUTHOR(S): Graduate School of Science and Engineering, Yamagata CORPORATE SOURCE: University, Yamagata, 992-8510, Japan SOURCE: Polymers for Advanced Technologies (2002), 13(8), 601-604 CODEN: PADTE5; ISSN: 1042-7147 PUBLISHER: John Wiley & Sons Ltd.

Journal

DOCUMENT TYPE:

English

LANGUAGE:

AB Efficient organic electroluminescent (EL) devices were fabricated using a phosphorescent complex, tris(2-phenylpyridine)-iridium, Ir(ppy)3, as emitter and a buffer layer of tetraphenyldiamine-containing poly(arylene ether sulfone) (PTPDES) doped with tris(4-bromophenyl) aminium hexachloroantimonate (TBPAH) as electron acceptor. The complete device structure comprises glass substrate, ITO and Al electrodes and the active layers. Hole-transporting N,N'-di(1-naphthyl)-N,N'-diphenylbenzidine (α-NPD) was used as host for the emitter layer; 4,4'-N,N'-dicarbazolylbiphenyl (CBP), Ir(ppy)3, hole-blocking 2,9-dimethyl-4,7-diphenyl-1,10- phenanthroline (BCP), and electrontransporting tris(8-quinolinato)aluminum (III) (Alq3) were also included in the structure. The device demonstrated external quantum efficiency of 21.6% and luminous efficiency of 82 lm/W (77 cd/A) at 3.0 V. The high efficiency is due to the high quantum efficiency of phosphorescent Ir(ppy)3 and high luminous efficiency realized by the use of the polymer buffer layer.

IT 173394-17-7 173394-18-8

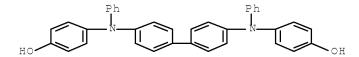
(PTPDES, anode buffer layer; electroluminescent devices with Ir-phenylpyridine/dicarbazolylbiphenyl emitter and poly(aminophenylene-ether-sulfone) buffer layer)

RN 173394-17-7 HCA

CN Phenol, 4,4'-[[1,1'-biphenyl]-4,4'-diylbis(phenylimino)]bis-, polymer with 1,1'-sulfonylbis[4-fluorobenzene] (CA INDEX NAME)

CM 1

CRN 121333-95-7 CMF C36 H28 N2 O2



CM 2

CRN 383-29-9 CMF C12 H8 F2 O2 S

RN 173394-18-8 HCA

CN Poly[oxy-1, 4-phenylenesulfonyl-1, 4-phenyleneoxy-1, 4-phenylene(phenylimino)[1,1'-biphenyl]-4,4'-diyl(phenylimino)-1,4-phenylene] (CA INDEX NAME)

PAGE 1-B

PAGE 1-A

CC 76-5 (Electric Phenomena)
Section cross-reference(s): 38, 73

ST iridium phenylpyridine emitter aminium polyaryleneethersulfone acceptor electroluminescent device; naphthylphenylbenzidine dicarbazolylbiphenyl iridium phenylpyridine quantum efficiency device; quinolinatoaluminum electron transport layer iridium phenylpyridine electroluminescent device

IT Electroluminescent devices

Electron acceptors

Glass substrates

Phosphorescence

(electroluminescent devices with

Ir-phenylpyridine/dicarbazolylbiphenyl emitter and
poly(aminophenylene-ether-sulfone) buffer layer)

IT Polysulfones, uses

(polyamine-polyether-, PTPDES, anode buffer layer; electroluminescent devices with

Ir-phenylpyridine/dicarbazolylbiphenyl emitter and
poly(aminophenylene-ether-sulfone) buffer layer)

IT Polyethers, uses

(polyamine-polysulfone-, PTPDES, anode buffer layer; electroluminescent devices with

Ir-phenylpyridine/dicarbazolylbiphenyl emitter and
poly(aminophenylene-ether-sulfone) buffer layer)

IT Polyamines

(polyether-polysulfone-, PTPDES, anode buffer layer; electroluminescent devices with

Ir-phenylpyridine/dicarbazolylbiphenyl emitter and
poly(aminophenylene-ether-sulfone) buffer layer)

IT 24964-91-8, Tris(4-bromophenyl)aminium hexachloroantimonate (Lewis acid dopant, PTPDES oxidant; electroluminescent devices with Ir-phenylpyridine/dicarbazolylbiphenyl emitter and poly(aminophenylene-ether-sulfone) buffer layer)

IT 173394-17-7 173394-18-8

(PTPDES, anode buffer layer; electroluminescent devices with Ir-phenylpyridine/dicarbazolylbiphenyl emitter and

poly(aminophenylene-ether-sulfone) buffer layer) ΙT 50926-11-9, ITO (anode; electroluminescent devices with Ir-phenylpyridine/dicarbazolylbiphenyl emitter and poly(aminophenylene-ether-sulfone) buffer layer) ΙT 7789-24-4, Lithium fluoride (LiF), uses (cathode interface layer; electroluminescent devices with Ir-phenylpyridine/dicarbazolylbiphenyl emitter and poly(aminophenylene-ether-sulfone) buffer layer) 7429-90-5, Aluminum, uses ΙT (cathode; electroluminescent devices with Ir-phenylpyridine/dicarbazolylbiphenyl emitter and poly(aminophenylene-ether-sulfone) buffer layer) 2085-33-8, Tris(8-quinolinolato)aluminum ΙT (electron transport layer; alectroluminescent devices with Ir-phenylpyridine/dicarbazolylbiphenyl emitter and poly(aminophenylene-ether-sulfone) buffer layer) ΙT 94928-86-6, Tris(2-phenylpyridine)iridium (emitter layer dopant; electroluminescent devices with Ir-phenylpyridine/dicarbazolylbiphenyl emitter and poly(aminophenylene-ether-sulfone) buffer layer) 4733-39-5, 2,9-Dimethyl-4,7-diphenyl-1,10-phenanthroline ΙT (hole blocking layer; electroluminescent devices with Ir-phenylpyridine/dicarbazolylbiphenyl emitter and poly(aminophenylene-ether-sulfone) buffer layer) 123847-85-8, N,N'-Di(1-naphthyl)-N,N'-diphenylbenzidine ΙT (hole transport layer; electroluminescent devices with Ir-phenylpyridine/dicarbazolylbiphenyl emitter and poly(aminophenylene-ether-sulfone) buffer layer) ΙT 58328-31-7, 4,4'-N,N'-Dicarbazolylbiphenyl (host emitter layer; electroluminescent devices with Ir-phenylpyridine/dicarbazolylbiphenyl emitter and poly(aminophenylene-ether-sulfone) buffer layer) RETABLE Referenced Author | Year | VOL | PG | Referenced Work | Referenced (RAU) | (RPY) | (RVL) | (RPG) | (RWK) | File Arai, M | 1997 | 91 | 21 | Synth Met | HCA Baldo, M | 1999 | 75 | 4 | Appl Phys Lett | HCA Berntsen, A | 1998 | 9 | 125 | Opt Mater | HCA Hung, L | 1997 | 70 | 152 | Appl Phys Lett | HCA Itoh, Y | 1990 | | Ext Abstr (51st Autu| Kido, J | 1998 | 73 | 2721 | Appl Phys Lett | HCA Kido, J Kido, J Sato, Y Tang, C | 1993 | 40 | 1342 | IEEE Trans Electron | HCA |1995 |7 |31 |Polym Adv Technol | |2000 |4105 |134 | Proc Soc of Photo-Op| Tang, C | 1987 | 51 | 913 | Appl Phys Lett | HCA | 1987 | 1987 | 1987 | 1987 | 1987 | 1988 | 1988 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | 1998 | RECORD (14 CITINGS) L66 ANSWER 15 OF 31 HCA COPYRIGHT 2011 ACS on STN ACCESSION NUMBER: 137:377262 HCA Full-text High efficiency multi-color electro-TITLE: phosphorescent OLEDs D'Andrade, Brian; Thompson, Mark E.; Forrest, Stephen INVENTOR(S):

PATENT ASSIGNEE(S): The Trustees of Princeton University, USA; The

University of Southern California

SOURCE: PCT Int. Appl., 50 pp.

CODEN: PIXXD2

DOCUMENT TYPE: Patent LANGUAGE: English

FAMILY ACC. NUM. COUNT: 1

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NO	W:							AZ,		BB	BG	BB	RY	B7.	$C\Delta$	СН	СИ	
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								MG,										
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		KG,	KΖ,	MD,	RU,	ТJ,	TM,	ΑT,	BE,	CH,	CY,	DE,	DK,	ES,	FI,	FR,	GB,	
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			114L O	• •						EP 2					A3 2			
										US 2					A1 2			
										WO 2						0020		
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ASSIGNMENT HISTORY FOR US PATENT AVAILABLE IN LSUS DISPLAY FORMAT

AB An organic light emitting device is described comprising an anode; a hole transporting layers; an emissive region; an electron transporting layer; and a cathode; wherein the emissive region is comprising a host material and a multiple emissive dopants to generate white emission, and wherein the emissive region is comprising a multiple bands and each emissive dopant is doped into a sep. band within the emissive region, and wherein at least one of the emissive dopants emits light by phosphorescence.

IT 134-85-0

(red emission layer; high efficiency multi-color electrophosphorescent organic LEDs)

RN 134-85-0 HCA

CN Methanone, (4-chlorophenyl)phenyl- (CA INDEX NAME)

IPCI H01L [ICM] IPCR C09K0011-06 [I,C*]; C09K0011-06 [I,A]; H01J0001-00 [I,C*]; H01J0001-74 [I,A]; H01J0029-18 $[I,C^*]$; H01J0029-32 [I,A]; H01L0051-50 $[I,C^*]$; H01L0051-50 [I,A]; H05B0033-14 [I,C*]; H05B0033-14 [I,A] CC 73-11 (Optical, Electron, and Mass Spectroscopy and Other Related Properties) Section cross-reference(s): 76 electro phosphorescence light emitting diode ST multi color Electroluminescent devices ΤТ (high efficiency multi-color electro-phosphorescent organic ΙT 376367-93-0 (blue phosphor dopant; high efficiency multi-color electrophosphorescent organic LEDs) 7429-90-5, Aluminum, uses ΙT (cathode; high efficiency multi-color electro-phosphorescent organic LEDs) 94928-86-6 ΙT (green emission dopant; high efficiency multi-color electrophosphorescent organic LEDs) 2085-33-8, Alq3 7789-24-4, Lithium fluoride (LiF), uses 16152-10-6 ΙT 50851-57-5, Poly(styrene sulfonic acid) 50926-11-9, Indium tin oxide 123847-85-8, α -NPD 126213-51-2, PEDOT 337526-88-2 (high efficiency multi-color electro-phosphorescent organic LEDs) 4733-39-5, 2,9-Dimethyl-4,7-diphenyl-1,10-phenanthroline(hole-blocking layer; high efficiency multi-color electro-phosphorescent organic LEDs) 134-85-0 ΙT (red emission layer; high efficiency multi-color electrophosphorescent organic LEDs) 343978-79-0 IT (red emissive layer dopant; high efficiency multi-color electrophosphorescent organic LEDs) RETABLE Referenced Author | Year | VOL | PG | Referenced Work | Referenced | File (RAU) |(RPY)|(RVL)|(RPG)| (RWK) 30 THERE ARE 30 CAPLUS RECORDS THAT CITE THIS OS.CITING REF COUNT: RECORD (46 CITINGS) L66 ANSWER 16 OF 31 HCA COPYRIGHT 2011 ACS on STN ACCESSION NUMBER: 137:208313 HCA Full-text TITLE: Photoconductive imaging members Liu, Ping; Hsiao, Cheng-kuo; Ong, Beng S.; Fuller, INVENTOR(S):

Silvestri, Markus R.

Timothy J.; Yuh, Huoy-jen; Cherniack, Helen R.;

PATENT ASSIGNEE(S): Xerox Corporation, USA

SOURCE: U.S., 12 pp.
CODEN: USXXAM

DOCUMENT TYPE: Patent LANGUAGE: English

FAMILY ACC. NUM. COUNT: 1

PATENT INFORMATION:

PATENT NO. KIND DATE APPLICATION NO. DATE

US 6444386 B1 20020903 US 2001-834292 20010413 <-
PRIORITY APPLN. INFO.: US 2001-834292 20010413 <-
ASSIGNMENT HISTORY FOR US PATENT AVAILABLE IN LSUS DISPLAY FORMAT

ASSIGNMENT HISTORY FOR US PATENT AVAILABLE IN LSUS DISPLAY FORMAT OTHER SOURCE(S): MARPAT 137:208313

AB A photoconductive imaging member contains (1) a supporting substrate, (2) a hole blocking layer, (3) a photogenerating layer, and (4) a charge transport layer. The hole blocking layer is generated from crosslinking an organosilane: SiRR1R2R3 (R = alkyl, aryl, with the substituent being halide, alkoxy, aryloxy, amino; R1-3 = alkyl, aryl, alkoxy, aryloxy, acyloxy, halide, cyano, and amino) in the presence of a hydroxy-functionalized polymer: (A)x(B-D-OH)y (A, B = resp. divalent and trivalent repeating units; D = divalent linkage; x, y = mole fractions of the repeating units of A and B, resp., and x = 0-0.99, yr = 0.01-1, x+y = 1).

IT 26355-01-19, 2-Hydroxyethyl methacrylate-methyl methacrylate copolymer

(hole blocking layer; photoconductive imaging members containing)

RN 26355-01-1 HCA

CN 2-Propenoic acid, 2-methyl-, 2-hydroxyethyl ester, polymer with methyl 2-methyl-2-propenoate (CA INDEX NAME)

CM 1

CRN 868-77-9 CMF C6 H10 O3

CM 2

CRN 80-62-6 CMF C5 H8 O2

INCL 430064000

IPCI G03G0005-14 [ICM, 7]

IPCR G03G0005-06 [I,C*]; G03G0005-06 [I,A]; G03G0005-14 [I,C*]; G03G0005-14
[I,A]

NCL 430/064.000

CC 74-2 (Radiation Chemistry, Photochemistry, and Photographic and Other

Reprographic Processes)

Section cross-reference(s): 35, 38

26355-01-1P, 2-Hydroxyethyl methacrylate-methyl methacrylate copolymer

> (hole blocking layer; photoconductive imaging members containing)

RETABLE

Referenced Author (RAU)		VOL PG (RVL) (RPG)	Referenced Work (RWK)	Referenced File
Baczek	+=====+ 1981		+=====================================	=+====== HCA
Hoffend	1985	ĺ	US 4560635 A	HCA
Hor	1985		US 4555463 A	HCA
Hor	1986		US 4587189 A	HCA
Keoshkerian	1996		US 5482811 A	HCA
Lu	1982		US 4338390 A	HCA
Melnyk	1990		US 4921773 A	HCA
Middleton	1964		US 3121006 A	HCA
Ong	2001		US 6287737 B1	HCA
Stolka	1981		US 4265990 A	HCA
Teuscher	1984		US 4464450 A	HCA
Yuh	1990		US 4921769 A	HCA
OS.CITING REF COUNT:	8	THERE ARE 8	CAPLUS RECORDS THAT	CITE THIS RECORD
		(8 CITINGS)		

L66 ANSWER 17 OF 31 HCA COPYRIGHT 2011 ACS on STN 136:207054 HCA Full-text ACCESSION NUMBER:

TITLE: Hole blocking effect on the organic electroluminescent

device using europium complex

AUTHOR(S): Kim, Jun Ho; Lee, Sang Phil; Kim, Jung Soo; Kim, Young

Kwan; Lee, Seung Hee

CORPORATE SOURCE: Department of Electrical & Control Engineering,

Hong-Ik, University, Seoul, 121-791, S. Korea

SOURCE: Molecular Crystals and Liquid Crystals Science and

Technology, Section A: Molecular Crystals and Liquid

Crystals (2001), 371, 455-458 CODEN: MCLCE9; ISSN: 1058-725X

PUBLISHER: Gordon & Breach Science Publishers

DOCUMENT TYPE: Journal LANGUAGE: English

The Eu complex, Eu(TTA)3(TPPO) [tris-(4,4,4-trifluoro-1-(2-thienyl)-butane-AΒ 1,3-dionate)-triphenyl phosphine oxide europium(III)] is known as the sharp red electroluminescent organic material at the wavelength of 615 nm, but its luminance is quite low. In this study, the complex's elec. and optical characteristics were improved using the hole blocking layer (HBL), BCP [2,9dimethyl-4,7-diphenyl-1,10-phenanthroline]. The device with a structure of ITO/TPD/Eu(TTA)3(TPPO)/BCP/Alq3/Li:Al/Al was fabricated and its photoluminescent and electroluminescent characteristics were investigated. It was found that the BCP layer with a thickness of 6 nm can block the holes from Eu complex efficiently to improve the EL characteristics of the device. Details on the elec. properties of these structures are also discussed.

TТ 12121-29-8

> (hole blocking effect on organic electroluminescent device using europium complex as emitter and bathocuproine as hole-blocking layer)

12121-29-8 HCA RN

Europium, tris[4,4,4-trifluoro-1-(2-thienyl)-1,3-butanedionato- κ 01, κ 03]bis(triphenylphosphine oxide- κ 0)- (CA INDEX NAME)

$$F3C$$

$$\overline{H}C$$

$$S$$

$$F3C$$

$$Ph3P$$

$$O$$

$$PPh3$$

$$F3C$$

$$F3C$$

CC 73-5 (Optical, Electron, and Mass Spectroscopy and Other Related Properties)

Section cross-reference(s): 74, 76

12121-29-8 ΙT

> (hole blocking effect on organic electroluminescent device using europium complex as emitter and bathocuproine as hole-blocking layer)

RETABLE

Referenced Author (RAU)	(RPY) (RVL)	(RPG)	(RWK)	Referenced File
Kido, J Kijima, Y Tsutsui, T	1994 65 1988	2124	Appl Phys Lett Spring MRS Appl Phys Lett	HCA HCA
OS.CITING REF COUNT:	-	RE ARE 3 CITINGS)	CAPLUS RECORDS THAT	CITE THIS RECORD

L66 ANSWER 18 OF 31 HCA COPYRIGHT 2011 ACS on STN 135:233846 HCA Full-text ACCESSION NUMBER:

Photoconductive hole blocking layer TITLE:

Ong, Beng S.; Liu, Ping; Hsiao, Cheng-kuo; Yuh, INVENTOR(S): Huoy-jen; Chambers, John S.; Pai, Damodar M.;

Silvestri, Markus R.; Carmichael, Kathleen M.

PATENT ASSIGNEE(S): Xerox Corporation, USA

SOURCE: U.S., 22 pp. CODEN: USXXAM

DOCUMENT TYPE: Patent

LANGUAGE: English

FAMILY ACC. NUM. COUNT: 1

PATENT INFORMATION:

PATENT NO.	KIND	DATE	APPLICATION NO.		DATE
US 6287737	В1	20010911	US 2000-579491		20000530 <
JP 2002023404	A	20020123	JP 2001-152568		20010522 <
PRIORITY APPLN. INFO.:			US 2000-579491	A	20000530 <
ASSIGNMENT HISTORY FOR	US PATEN	T AVATLABLE	IN LSUS DISPLAY	FORMAT	

OTHER SOURCE(S): MARPAT 135:233846

The present invention encompasses xerog. imaging and printing, including digital. A photoconductive imaging member is comprised of a supporting substrate, a hole blocking layer thereover, a photogenerating layer and a charge transport layer. The hole blocking layer is comprised of a crosslinked polymer derived from silyl-functionalized hydroxyalkyl polymer -(A)a-(b(SiX3))b-(D(E))c-(F(OH))d-(A, B, D, and F = segments of polymer backbone; E

= electron transporting moiety; X = halide, cyano, alkoxy, acyloxy, and aryloxy; a, b, c, and d = mole fractions of repeating monomer units, satisfying a+b+c+d=1) reacted with an organosilane RSiR1R2R3 (R= alkyl, alkyl, aryl; R1-3 = alkyl, aryl, alkoxy, aryloxy, acyloxy, halogen, cyano, and amino) and water. The presence of a hydroxyl group enables the addition of water to the coating solution without substantially causing phase separation, and also accelerates the curing or crosslinking the hole blocking laver.

68-12-2, N,N-Dimethylformamide, reactions ΙT (electrophotog, photoconductive hole blocking layer prepared from)

68-12-2 HCA RN

Formamide, N, N-dimethyl- (CA INDEX NAME) CN

INCL 430058800

IPCI G03G0005-047 [ICM, 7]; G03G0005-043 [ICM, 7, C*]; G03G0005-14 [ICS, 7]

IPCR C08F0008-00 [I,C*]; C08F0008-42 [I,A]; C08F0212-00 [I,C*]; C08F0212-02 [I,A]; C08F0220-00 [I,C*]; C08F0220-12 [I,A]; C08F0230-00 [I,C*]; C08F0230-08 [I,A]; G03G0005-043 [I,C*]; G03G0005-047 [I,A]; G03G0005-05 [I,C*]; G03G0005-05 [I,A]; G03G0005-14 [I,C*]; G03G0005-14 [I,A]

NCL 430/058.800; 430/058.650; 430/059.400; 430/064.000

CC 74-3 (Radiation Chemistry, Photochemistry, and Photographic and Other Reprographic Processes)

Section cross-reference(s): 35, 38

ΙT 68-12-2, N,N-Dimethylformamide, reactions 1592-20-7,

4-Vinylbenzyl chloride 36232-49-2,

9-Dicyanomethylenefluorene-4-carboxylic acid

(electrophotog. photoconductive hole blocking layer prepared from)

RETABLE

Referenced Author (RAU)	Year (RPY)	, , , , , , ,	Referenced Work (RWK)	File
Burt	 1996		-+ US 5493016	HCA
Duff	1997	1	US 5645965	HCA
Keoshkerian	1996	1	US 5482811	HCA
Liu	1999		US 5874193	HCA
Mayo	1995	1	US 5473064	HCA
Ong	1999		US 5871877	HCA
Springett	2000		US 6030735	HCA
Stolka	1981		US 4265990	HCA
OS.CITING REF COUNT:	33	THERE ARE :	33 CAPLUS RECORDS CITINGS)	THAT CITE THIS

CORD (33 CITINGS)

L66 ANSWER 19 OF 31 HCA COPYRIGHT 2011 ACS on STN

ACCESSION NUMBER: 135:11837 HCA Full-text

An Efficient Pyridine- and Oxadiazole-Containing TITLE: Hole-Blocking Material for Organic Light-Emitting Diodes: Synthesis, Crystal Structure, and Device

Performance

Wang, Changsheng; Jung, Gun-Young; Hua, Yulin; AUTHOR(S):

> Pearson, Christopher; Bryce, Martin R.; Petty, Michael C.; Batsanov, Andrei S.; Goeta, Andres E.; Howard,

Judith A. K.

CORPORATE SOURCE: Department of Chemistry and School of Engineering,

University of Durham, Durham, DH1 3LE, UK

SOURCE: Chemistry of Materials (2001), 13(4),

1167-1173

CODEN: CMATEX; ISSN: 0897-4756

PUBLISHER: American Chemical Society

DOCUMENT TYPE: Journal LANGUAGE: English

The authors focus on the synthesis and structure of the new bis(1,3,4oxadiazole) system 2,5-bis[2-(4-tert-butylphenyl)-1,3,4- oxadiazol-5yl]pyridine (PDPyDP). The authors have fabricated light-emitting diodes

(LEDs) using

poly[2-methoxy-5-(2-ethylhexoxy)-1,4-phenylene vinylene] (MEH-PPV) as the emissive material, with and without a thermally evaporated electroninjection/hole-blocking layer of either PDPyDP or its vinylene analog (E)-1,2bis[2-(4-tert-butylphenyl)-1,3,4-oxadiazol-5-yl]ethene (PDVDP) or its phenylene analog 1,4-bis[2-(4-tert-butylphenyl)-1,3,4- oxadiazol-5-yl]benzene (PDPDP). PDPDP is the para isomer of OXD-7, which is a widely used mol. electron-transporting material. Electroluminescence spectra indicate that light is emitted only from the MEH-PPV layer. Using Al as the cathode, the bilayer LED with PDPyDP is considerably more efficient than the corresponding single-layer device or devices with PDVDP or PDPDP as the electron-injection

1710-98-1, 4-tert-Butylbenzoyl chloride IT

(efficient pyridine- and oxadiazole-containing holeblocking material for organic light-emitting diodes: synthesis, crystal structure, and device performance)

1710-98-1 HCA RN

Benzoyl chloride, 4-(1,1-dimethylethyl)- (CA INDEX NAME) CN

CC 73-11 (Optical, Electron, and Mass Spectroscopy and Other Related Properties)

Section cross-reference(s): 28, 75, 76

1710-98-1, 4-tert-Butylbenzoyl chloride ΤT 6011-55-8,

Pyridine-2,5-dicarboxylic acid dihydrazide 7803-57-8, Hydrazine hydrate (efficient pyridine- and oxadiazole-containing hole-

blocking material for organic light-emitting diodes: synthesis,

crystal structure, and device performance)

RETABLE

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Tian, J	1995	7	2190	· ·	HCA
Wang, C	12000	12	217	· ·	HCA
OS.CITING REF COUNT:	70			O CAPLUS RECORDS THAT	CITE THIS
		RECO	אט (/ ד	CITINGS)	

L66 ANSWER 20 OF 31 HCA COPYRIGHT 2011 ACS on STN ACCESSION NUMBER: 135:6245 HCA Full-text

TITLE: Light-Emitting Devices Based on a

Poly(p-phenylenevinylene) Statistical Copolymer with

Oligo(ethylene oxide) Side Groups

AUTHOR(S): Morgado, J.; Cacialli, F.; Friend, R. H.; Chuah, B.

S.; Rost, H.; Holmes, A. B.

CORPORATE SOURCE: Departamento de Engenharia Quimica, Instituto Superior

Tecnico, Lisbon, P-1049-001, Port.

SOURCE: Macromolecules (2001), 34(9), 3094-3099

CODEN: MAMOBX; ISSN: 0024-9297

PUBLISHER: American Chemical Society

DOCUMENT TYPE: Journal LANGUAGE: English

The photoluminescence and electroluminescence were studied of the statistical copolymer poly[2,5-bis(dimethyloctylsilyl)-1,4- phenylenevinylene-2,5- bis(triethoxymethoxy)-1,4-phenylenevinylene], BDMOS-co-BTEM-PPV. The BDMOS-co-BTEM-PPV copolymer is designed to combine the high luminescence efficiency of BDMOS-PPV with the ion-coordinating ability of BTEM-PPV. The photoluminescence efficiency increased to about 17% from 8.8% for BTEM-PPV. In single-layer light-emitting diode test structures with calcium (aluminum) cathode the luminance was up to 1300 (10) cd/m2 with an efficiency of ≈ 0.5 (0.01) cd/A. The ITO/BDMOS-co-BTEM-PPV:LiTf (8%)/Al device structures display behavior typical of light-emitting electrochem. cells, LECs, with efficiency up to 0.03 cd/A. The statistical copolymer contributes to the photoluminescence efficiency and provides sufficient ion coordination for LEC applications.

(hole-blocking/electron transport layer; preparation and luminescence and ion coordinating efficiency of poly(bis(dimethyloctylsilyl)-bis(triethoxymethoxy)-p-phenylenevinylene) for LEDs)

RN 9011-14-7 HCA

 ${\tt CN}$ 2-Propenoic acid, 2-methyl-, methyl ester, homopolymer (CA INDEX NAME)

CM 1

CRN 80-62-6 CMF C5 H8 O2

CC 37-5 (Plastics Manufacture and Processing)

Section cross-reference(s): 73

IT 852-38-0, PBD 9011-14-7, Poly(methyl methacrylate)
(hole-blocking/electron transport layer; preparation and
luminescence and ion coordinating efficiency of
poly(bis(dimethyloctylsilyl)-bis(triethoxymethoxy)-p-phenylenevinylene)
for LEDs)

Referenced Author | Year | VOL | PG | Referenced Work | Referenced

RETABLE

(RAU)	(RPY)	(RVL)	(RPG)	(RWK)	File
Blom, P			3308	Appl Phys Lett	HCA
Bredas, J	1994	217	507	Chem Phys Lett	HCA
Brown, A	1992	61	2793	Appl Phys Lett	HCA
Burroughes, J	1990	347	539	Nature	HCA
Chu, H	1999	101	216	Synth Met	HCA
Chuah, B	1997	91	279	Synth Met	HCA
Demello, J	1997	19	230	Adv Mater	HCA
Demello, J	1998	57	12951	Phys Rev B	HCA
Demello, J	2000	85	421	Phys Rev Lett	HCA
Friend, R	1999	397	121	Nature	HCA
Greenham, N	1994	6	491	Adv Mater	HCA
Halls, J	1999	160	5721	Phys Rev B	HCA
Helbig, M	1993	194	1607	Makromol Chem	HCA
Holzer, L	1999	102	1022	Synth Met	HCA
Holzer, L	1999	100	71	Synth Met	HCA
Hwang, D	1997	125	111	Macromol Symp	
Janietz, S	1998	73	2453	Appl Phys Lett	HCA
Kim, J	1998	84	6859	J Appl Phys	HCA
Kim, S	1996	8	979	Adv Mater	HCA
Kraft, A	1998	37	402	Angew Chem, Int Ed E	[
Lebedev, E	1997	71	2686	Appl Phys Lett	HCA
Morgado, J	1999	85	1784	J Appl Phys	HCA
Morgado, J	1999	186	6392	J Appl Phys	HCA
Pei, Q	1996	118	3922	J Am Chem Soc	HCA
Pei, Q	1996	118	7416	J Am Chem Soc	HCA
Pei, Q	1995	269	1086	Science	HCA
Pommerehne, J	1995	7	5517	Adv Mater	1
Rost, H	1999	102	937	Synth Met	HCA
Wu, P	1995	267	441	Mol Cryst Liq Cryst	1
Yu, G	1996	259	465	Chem Phys Lett	HCA
OS.CITING REF COUNT:	38	THER	E ARE	38 CAPLUS RECORDS THAT	CITE THIS

RECORD (38 CITINGS)

L66 ANSWER 21 OF 31 HCA COPYRIGHT 2011 ACS on STN ACCESSION NUMBER: 133:193562 HCA Full-text

TITLE: New polyquinoline copolymers: synthesis, optical,

luminescent, and hole-blocking/electron-transporting

properties

AUTHOR(S): Kim, Jong Lae; Kim, Jai Kyeong; Cho, Hyun Nam; Kim,

Dong Young; Kim, Chung Yup; Hong, Sung Il

CORPORATE SOURCE: Department of Fiber Polymer Science, Seoul National

University, Seoul, 151-742, S. Korea

SOURCE: Macromolecules (2000), 33(16), 5880-5885

CODEN: MAMOBX; ISSN: 0024-9297

PUBLISHER: American Chemical Society

DOCUMENT TYPE: Journal LANGUAGE: English

AB A series of polyquinolines containing the 9,9-dihexylfluorene unit in the main chain were synthesized via Friedlaender quinoline synthesis in good yields. The thermal, optical, luminescent, electrochem., and hole-blocking/electron-transporting properties of these polyquinolines were examined The glass transition temps. were in the range 195-243°C, and these polyquinolines had initial decomposition temps. of >388°C. Their optical and luminescent properties varied with the chain rigidity and conjugation length. Cyclic voltammetry studies reveal that these polyquinolines undergo irreversible oxidation onset around -6.0 eV, and their LUMO level ranged from -2.78 to -3.21 eV. The application of two of these polyquinolines as a hole-blocking/electron-transporting layer in polymeric LEDs was demonstrated.

IT 106500-65-6P, 4,4'-Diamino-3,3'-dibenzoyldiphenyl sulfide (monomer; preparation and optical, luminescent and hole-blocking/electron-transporting properties of)

RN 106500-65-6 HCA

CN Methanone, [thiobis(6-amino-3,1-phenylene)]bis[phenyl- (9CI) (CA INDEX NAME)

$$\begin{array}{c|c} & & & \\ & & & \\ \text{Ph} - & & \\ & & \\ \text{H}_2\text{N} & & \\ & & \\ & & \\ \end{array}$$

IT 222416-60-6 222416-62-8

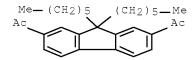
(optical, luminescent and hole-blocking
/electron-transporting properties of)

RN 222416-60-6 HCA

CN Ethanone, 1,1'-(9,9-dihexyl-9H-fluorene-2,7-diyl)bis-, polymer with [oxybis(6-amino-3,1-phenylene)]bis[phenylmethanone] (9CI) (CA INDEX NAME)

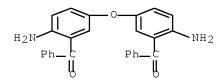
CM 1

CRN 222416-59-3 CMF C29 H38 O2



CM 2

CRN 59827-14-4 CMF C26 H20 N2 O3

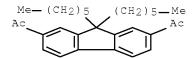


RN 222416-62-8 HCA

CN Ethanone, 1,1'-(9,9-dihexyl-9H-fluorene-2,7-diyl)bis-, polymer with (4,4'-diamino[1,1'-biphenyl]-3,3'-diyl)bis[phenylmethanone] (9CI) (CA INDEX NAME)

CM 1

CRN 222416-59-3 CMF C29 H38 O2



CM 2

CRN 71713-10-5 CMF C26 H20 N2 O2

$$\begin{array}{c|c} & & & \circ \\ \text{Ph-} & & & \circ \\ \text{H}_2 \text{N} & & & \text{NH}_2 \end{array}$$

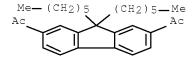
IT 289471-87-0P 289471-89-2P, 2,7-Diacetyl-9,9-dihexylfluorene-4,4'-Diamino-3,3'-dibenzoylstilbene copolymer (preparation and optical, luminescent and hole-blocking
/electron-transporting properties of)

RN 289471-87-0 HCA

CN Ethanone, 1,1'-(9,9-dihexyl-9H-fluorene-2,7-diyl)bis-, polymer with [thiobis(6-amino-3,1-phenylene)]bis[phenylmethanone] (9CI) (CA INDEX NAME)

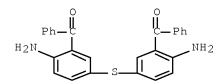
CM 1

CRN 222416-59-3 CMF C29 H38 O2



CM 2

CRN 106500-65-6 CMF C26 H20 N2 O2 S

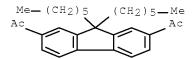


RN 289471-89-2 HCA

CN Ethanone, 1,1'-(9,9-dihexyl-9H-fluorene-2,7-diyl)bis-, polymer with [1,2-ethenediylbis(6-amino-3,1-phenylene)]bis[phenylmethanone] (9CI) (CA INDEX NAME)

CM 1

CRN 222416-59-3 CMF C29 H38 O2



CM 2

CRN 94751-92-5 CMF C28 H22 N2 O2

CC 35-5 (Chemistry of Synthetic High Polymers) Section cross-reference(s): 36, 72, 73, 76

IT 106500-65-6P, 4,4'-Diamino-3,3'-dibenzoyldiphenyl sulfide (monomer; preparation and optical, luminescent and hole-blocking/electron-transporting properties of)

IT 222416-60-6 222416-61-7 222416-62-8 222416-63-9 (optical, luminescent and hole-blocking

/electron-transporting properties of)
T 289471-87-09 289471-88-1P,

2,7-Diacetyl-9,9-dihexylfluorene-4,4'-Diamino-3,3'-dibenzoyldiphenyl sulfide copolymer, SRU 289471-89-2P,

2,7-Diacetyl-9,9-dihexylfluorene-4,4'-Diamino-3,3'-dibenzoylstilbene copolymer 289471-90-5P, 2,7-Diacetyl-9,9-dihexylfluorene-4,4'-Diamino-

3,3'-dibenzoylstilbene copolymer, SRU

(preparation and optical, luminescent and hole-blocking /electron-transporting properties of)

RETABLE

KETABLE					
Referenced Author	Year	VOL	PG	Referenced Work	Referenced
(RAU)	(RPY)	(RVL)	(RPG)	(RWK)	File
	+====	+====	+=====	+=========	+=======
Abkowitz, M	1992	83	937	Solid State Commun	HCA
Agrawal, A	1992	196	2837	J Phys Chem	HCA
Agrawal, A	1993	26	895	Macromolecules	HCA
Burn, P	1993	115	10117	J Am Chem Soc	HCA
Burrough, J	1990	347	539	Nature	
Cao, Y	1999	397	414	Nature	HCA
Cho, H	1999	32	1476	Macromolecules	HCA
Fukuda, M	1990	31	2465	J Polym Sci, Polym C	
Janietz, S	1997	19	403	Adv Mater	HCA
Jenekhe, S	1997	19	409	Chem Mater	HCA
Jenekhe, S	1994	265	765	Science	HCA
Kim, D	1997	3418	151	Proc SPIE Int Soc Op	
Kim, J	1999	32	2065	Macromolecules	HCA
Kim, K	1992	46	1	J Appl Polym Sci	HCA
Norris, S	1976	19	496	Macromolecules	HCA
Ohmori, Y	1991	130	L1941	Jpn J Appl Phys	
Osaheni, J	1994	27	739	Macromolecules	HCA
Parker, I	1994	165	1272	Appl Phys Lett	HCA
Pei, Q	1996	118	7416	J Am Chem Soc	HCA
Pelter, M	1990	23	2418	Macromolecules	HCA
Pichler, K	1997	355	829	Philos Trans R Soc L	HCA
Pommerehne, J	1995	7	551	Adv Mater	HCA
Stille, J	1981	14	870	Macromolecules	HCA
Strukelj, M	1995	267	1969	Science	HCA
Sybert, P	1981	14	493	Macromolecules	HCA
Tani, H	1963	36	391	Bull Chem Soc Jpn	
Tunney, S	1987	20	258	Macromolecules	HCA
Vancraeynest, W	1980	13	1361	Macromolecules	HCA
Yu, W	1998	120	11808	J Am Chem Soc	HCA
Zhang, C	1994	162	35	Synth Met	HCA
Zhang, X	1999	32	7422	Macromolecules	HCA

Zimmermann, E | 1985 | 18 | 321 | Macromolecules | HCA

OS.CITING REF COUNT: 74 THERE ARE 74 CAPLUS RECORDS THAT CITE THIS

RECORD (74 CITINGS)

L66 ANSWER 22 OF 31 HCA COPYRIGHT 2011 ACS on STN ACCESSION NUMBER: 133:24680 HCA Full-text
TITLE: Photoconductive imaging member

INVENTOR(S): Jennings, Carol A.; Murti, Dasarao K.; Smith, Paul F.;

McAneney, Gwynne E.; Hor, Ah-Mee; Gardner, Sandra J.;

Ong, Beng S.

PATENT ASSIGNEE(S): Xerox Corp., USA SOURCE: U.S., 12 pp. CODEN: USXXAM

DOCUMENT TYPE: Patent LANGUAGE: English

FAMILY ACC. NUM. COUNT: 1

PATENT INFORMATION:

PATENT NO. KIND DATE APPLICATION NO. DATE

US 6074791 A 20000613 US 1999-258379 19990226 <-PRIORITY APPLN. INFO.: US 1999-258379 19990226 <--

ASSIGNMENT HISTORY FOR US PATENT AVAILABLE IN LSUS DISPLAY FORMAT

OTHER SOURCE(S): MARPAT 133:24680

AB A photoconductive imaging member comprises a supporting substrate, a hole-blocking layer, a photogenerating layer, and a charge-transporting layer, wherein the hole-blocking layer comprises a metal oxide prepared by a sol-gel process.

IT 9003-22-9, Vinyl acetate-vinyl chloride copolymer 24937-78-8, Ethylene-vinyl acetate copolymer (electrophotog. photoreceptors with hole-blocking

le construire de la les construires de la les construires de la construire de la construire

layers containing metal oxides and)

RN 9003-22-9 HCA

CN Acetic acid ethenyl ester, polymer with chloroethene (CA INDEX NAME)

CM 1

CRN 108-05-4 CMF C4 H6 O2

AcO-CH = CH2

CM 2

CRN 75-01-4 CMF C2 H3 C1

H2C ___ CH__C1

RN 24937-78-8 HCA

CN Acetic acid ethenyl ester, polymer with ethene (CA INDEX NAME)

CM 1

CRN 108-05-4 CMF C4 H6 O2

Aco-CH-CH2

2 CM

CRN 74-85-1 CMF C2 H4

H2C==CH2

INCL 430058800

IPCI G03G0005-10 [ICM, 7]

IPCR G03G0005-06 [I,C*]; G03G0005-06 [I,A]; G03G0005-14 [I,C*]; G03G0005-14 [I,A]

NCL 430/058.800; 430/059.400; 430/065.000

CC 74-3 (Radiation Chemistry, Photochemistry, and Photographic and Other Reprographic Processes)

ΙT 9002-85-1, Poly(vinylidene chloride) 9002-89-5, Poly(vinyl alcohol) 9003-01-4, Poly(acrylic acid) 9003-22-9, Vinyl acetate-vinyl chloride copolymer 9003-39-8, Poly(vinylpyrrolidone) 9003-47-8, Poly(vinylpyridine) 9004-57-3, Ethylcellulose 9004-64-2, Hydroxypropylcellulose 9004-67-5, Methylcellulose 9005-25-8, Starch, uses 24937-78-8, Ethylene-vinyl acetate copolymer 25322-68-3, Poly(ethylene oxide) 25322-69-4, Poly(propylene oxide) (electrophotog. photoreceptors with hole-blocking

layers containing metal oxides and)

RETABLE

Referenced Author (RAU)	Year VOL (RPY) (RVL)	(RPG)	Referenced Work (RWK)	Referenced File
Arnal, P	-+====+==== 1997 9	+===== 694	=+====================================	-+====== HCA
Ashiya	11996	1004	US 5582948	HCA
Badesha	11992	1	US 5116703	HCA
	11997 180	13157	J Am Ceram Soc	HCA
Barbe, C		•	·	•
Brinker, C	1990	21	Sol-Gel Science, Cha	·
Burt	1996		US 5493016	HCA
Burt	1996		US 5521306	HCA
Duff	1997		US 5645965	HCA
Flory, P	1974 57	7	Chem Society	HCA
Hongo	1994		US 5286591	HCA
Hor	1986		US 4587189	HCA
Katayama	1996		US 5489496	HCA
Keoshkerian	1996		US 5482811	HCA
Livage, J	1990 73	717	Mat Res Soc Symp Pro	
Lu	1982		US 4338390	HCA
Mayo	1995		US 5473064	HCA
O'Regan, B	1990 94	8720	J Phys Chem	HCA
Yu	1991		US 5013624	
OS.CITING REF COUNT:	5 THER	E ARE	5 CAPLUS RECORDS THAT	CITE THIS RECOF
	(5.0	TTTMGS)	

DRD (5 CITINGS)

L66 ANSWER 23 OF 31 HCA COPYRIGHT 2011 ACS on STN ACCESSION NUMBER: 129:101428 HCA Full-text

ORIGINAL REFERENCE NO.: 129:20745a,20748a

TITLE: Concentration effects on charge transport in dye doped

polymer light emitting diodes

AUTHOR(S): Nunzi, J. -M.; Gautier-Thianche, E.; Lorin, A.; Denis,

C.; Raimond, P.; Sentein, C.

LETI (CEA-Technologies Avancees), DEIN, Service de CORPORATE SOURCE:

Physique Electronique, Groupe Composants Organiques,

CEA / Saclay, Gif sur Yvette, 91191, Fr.

Proceedings of SPIE-The International Society for SOURCE:

Optical Engineering (1998), 3281 (Polymer

Photonic Devices), 302-309

CODEN: PSISDG; ISSN: 0277-786X

SPIE-The International Society for Optical Engineering PUBLISHER:

DOCUMENT TYPE: Journal English LANGUAGE:

Light emitting diodes made of a single spin-coated layer of poly(9-AΒ vinylcarbazole) doped with coumarin-515 dye were studied. The influence of dye concentration on emission and elec. characteristics is evidenced. Two different regimes are identified. At low concns., apparent hole injection barrier raises, holes are trapped and mobility decreases. External quantum efficiency increases with concentration At concns. larger than 10 %wt, coumarin aggregates, photoluminescence yield drops and electroluminescence yield increases up to 0.1 %-photons per electron. We show that using coumarin dye in a single-layer diode improves electron-hole injection and recombination balance more than using an addnl. hole-blocking layer.

ΤТ 206364-60-5

> (hole blocking layer in poly(9-vinylcarbazole) blue electroluminescent device)

206364-60-5 HCA RN

CN 2-Propenoic acid, 2-methyl-, 4-[5-[4-(1,1-dimethylethyl)phenyl]-1,3,4oxadiazol-2-yl]phenyl ester, homopolymer (CA INDEX NAME)

CM 1

CRN 206364-59-2 CMF C22 H22 N2 O3

CC 73-5 (Optical, Electron, and Mass Spectroscopy and Other Related Properties)

Section cross-reference(s): 38, 76

ΙT 206364-60-5

> (hole blocking layer in poly(9-vinylcarbazole) blue electroluminescent device)

RETABLE

Referenced Author	Year	VOL	PG	Referenced Work	Referenced
(RAU)	(RPY)	(RVL)	(RPG)	(RWK)	File
	+====	+====	+=====	+========	+========
Adachi, C	1990	56	799	Appl Phys Lett	HCA
Gautier, E	1996	169	1071	Appl Phys Lett	HCA
Gautier, E	1996	81	197	Synth Met	HCA
Gill, W	1976		63	Photoconductivity an	
Kido, J	1994	64	815	Appl Phys Lett	HCA
Kido, J	1995	167	2281	Appl Phys Lett	HCA
Nishino, H	1995	168	243	Synth Met	HCA
Pai, D	1970	52	2285	J Chem Phys	HCA
Schlatmann, A	1996	169	1764	Appl Phys Lett	HCA
Strukelj, M	1995	267	1969	Science	HCA
Tokuhisa, H	1995	166	3433	Appl Phys Lett	HCA
van Slyke, S	1996	169	2160	Appl Phys Lett	HCA
Vestweber, H	1994	64	141	Synth Met	HCA
Weissmantel, C	1981		361	Grundlagen der Festk	
Wu, C	1997	44	1269	IEEE Trans Electr De	HCA
Zhang, C	1995	72	185	Synth Met	HCA

L66 ANSWER 24 OF 31 HCA COPYRIGHT 2011 ACS on STN ACCESSION NUMBER: 128:3895 HCA Full-text

ORIGINAL REFERENCE NO.: 128:847a,850a

TITLE: Synthesis and Characterization of Aromatic

Poly(1,3,5-triazine-ether)s for Electroluminescent

Devices

AUTHOR(S): Fink, Ralf; Frenz, Carsten; Thelakkat, Mukundan;

Schmidt, Hans-Werner

CORPORATE SOURCE: Makromolekulare Chemie I and Bayreuther Institut fuer

Makromolekuelforschung (BIMF), Universitaet Bayreuth,

Bayreuth, 95440, Germany

SOURCE: Macromolecules (1997), 30(26), 8177-8181

CODEN: MAMOBX; ISSN: 0024-9297

PUBLISHER: American Chemical Society

DOCUMENT TYPE: Journal LANGUAGE: English

AB Various difluoro functionalized aromatic 1,3,5-triazine monomers were prepared A series of poly(1,3,5-triazine-ether)s was synthesized by polycondensation with 4,4'-hexafluoroisopropylidenebis[phenol]. The polymers have excellent thermal stability and are amorphous with glass transition temps. in the range 190-250°. In order to examine the potential application these polymers may possess for use in organic electroluminescent devices, the redox properties were studied by cyclic voltammetry. The monomers have high electron affinities and reach LUMO values in the range of -2.7 to -3.1 eV. This opens the possibility to utilize 1,3,5-triazine-containing materials as electron injecting/hole blocking layers in light emitting devices (LEDs). Initial LED results are in accordance with these high electron affinities.

IT 66-77-3, 1-Naphthaldehyde 455-19-6,

4-(Trifluoromethyl)benzaldehyde 872-85-5,

4-Pyridinecarboxaldehyde 4363-93-3, 4-Formylquinoline

(reactant; in synthesis of difluoro aromatic triazine monomers for preparation $% \left(\frac{1}{2}\right) =\frac{1}{2}\left(\frac{1}{2}\right) +\frac{1}{2}\left(\frac{1}{2}$

of polymers as hole blocking/electron transport

layers for use in multilayer light emitting devices)

RN 66-77-3 HCA

CN 1-Naphthalenecarboxaldehyde (CA INDEX NAME)

RN 455-19-6 HCA

CN Benzaldehyde, 4-(trifluoromethyl)- (CA INDEX NAME)

RN 872-85-5 HCA

CN 4-Pyridinecarboxaldehyde (CA INDEX NAME)

RN 4363-93-3 HCA

CN 4-Quinolinecarboxaldehyde (CA INDEX NAME)

IT 100-52-7, Benzaldehyde, reactions

(reactant; in synthesis of difluoro aromatic triazine monomers for synthesis of polymers as hole blocking/electron

transport layers for use in multilayer light emitting devices)

RN 100-52-7 HCA

CN Benzaldehyde (CA INDEX NAME)

CC 35-2 (Chemistry of Synthetic High Polymers)

IT 62-53-3, Benzenamine, reactions 64-17-5, Ethanol, reactions

66-77-3, 1-Naphthaldehyde 455-19-6,

4-(Trifluoromethyl)benzaldehyde 872-85-5,

4-Pyridinecarboxaldehyde 1194-02-1, 4-Fluorobenzonitrile

4363-93-3, 4-Formylquinoline

(reactant; in synthesis of difluoro aromatic triazine monomers for preparation $% \left(\frac{1}{2}\right) =\frac{1}{2}\left(\frac{1}{2}\right) +\frac{1}{2}\left(\frac{1}{2}$

of polymers as hole blocking/electron transport

layers for use in multilayer light emitting devices)

IT 100-52-7, Benzaldehyde, reactions

(reactant; in synthesis of difluoro aromatic triazine monomers for synthesis of polymers as hole blocking/electron

transport layers for use in multilayer light emitting devices)

RETABLE

Referenced Author (RAU)	(RPY)	. , , ,	(RPG)	Referenced Work (RWK)	Referenced File
Adachi, C		57	531	Appl Phys Lett	HCA
Bard, A	1980		634	Electrochemical Meth	.
Bettenhausen, J	1996	8	507	Adv Mater	HCA
Borovik, V	1991	4	196	Sib Khim Zh	
Brown, A	1992	61	2793	Appl Phys Lett	HCA
Buchwald, E	1995	7	839	Adv Mater 7	HCA
Burroughes, J	1990	347	539	Nature (London)	HCA
Gmeiner, J	1993	44	201	Acta Polym	HCA
Kido, J	1993	32	L917	Jpn J Appl Phys	HCA
Koepp, H	1960	164	483	Z Electrochem	HCA
Moratti, S	1995	71	2117	Synth Met	HCA
Perrin, D	1988			Purification of Labo	
Pommerehne, J	1995	7	551	Adv Mater	HCA
Rossbach, V	1992			Handbook of Polymer	
Shirota, Y	1994	165	1807	Appl Phys Lett	HCA
Solomon, D	1972	1	1	Step-Growth Polymeri	
Strukelj, M	1995	117	11976	J Am Chem Soc	HCA
Strukelj, M	1995		1267	Science	
Tang, C	1987	51	913	Appl Phys Lett	HCA
Von Seggern, H	1994	1	2023	Macromol Chem Phys	HCA
Yamamoto, T	1996	118	3939	J Am Chem Soc	
Yang, Y	1995	77	1694	J Appl Phys	HCA
OS.CITING REF COUNT:	66			56 CAPLUS RECORDS THAT CITINGS)	CITE THIS

L66 ANSWER 25 OF 31 HCA COPYRIGHT 2011 ACS on STN ACCESSION NUMBER: 127:323987 HCA Full-text

ORIGINAL REFERENCE NO.: 127:63427a,63430a

TITLE: Multilayer light emitting diodes based on columnar

discotics

AUTHOR(S): Stapff, Inga H.; Stumpflen, Volker; Wendorff, Joachim

H.; Spohn, Daniela B.; Mobius, Dietmar

CORPORATE SOURCE: Fachbereich Physikalische Chemie und

Wissenschaftliches Zentrum fiir

Materialwissenschaften, Philipps-Universitat Marburg,

Margurg, D-35032, Germany

SOURCE: Liquid Crystals (1997), 23(4), 613-617

CODEN: LICRE6; ISSN: 0267-8292

PUBLISHER: Taylor & Francis

DOCUMENT TYPE: Journal LANGUAGE: English

AB Columnar discotics were used as the hole transporting layer in single layer, two layer and three layer light emitting diodes because of the unusually large hole mobility of such materials. The observations are that the onset fields are small compared with most devices using non-discotic hole transporting layers, that these values are strongly reduced with increasing number of layers, that the orientation of the columns along the layer film normal causes

a further decrease of the onset voltage and finally that the quantum efficiencies increase significantly as the number of layers is increased.

IT 1120-28-1, Arachidic acid methyl ester

(hole blocking layer; light emitting diode containing columnar discotic hole transport layer and)

RN 1120-28-1 HCA

CN Eicosanoic acid, methyl ester (CA INDEX NAME)

CC 73-5 (Optical, Electron, and Mass Spectroscopy and Other Related Properties)

Section cross-reference(s): 75, 76

IT 1120-28-1, Arachidic acid methyl ester 197786-11-1 (hole blocking layer; light emitting diode containing columnar discotic hole transport layer and)

RETABLE

Referenced Author (RAU)		(RVL)	(RPG)	Referenced Work (RWK)	Referenced File
Adachi, C	•	-+==== 55	1489	 Appl Phys Lett	HCA
Adachi, C	11988	127	713	Jpn J appl Phys	İ
Adam, D	1994	į 7	276	Adv Mater	İ
Adam, D	1994	371	1141	Nature	HCA
Adam, D	1993	70	457	Phys Rev Lett	HCA
Blodgett, K	1935	57	1007	J Am chem Soc	HCA
Braun, D	1991	58	1982	Appl Phys Lett	HCA
Burroughes, J	1990	347	539	Nature	HCA
Christ, T	1997	19	48	Adv Mater	HCA
Christ, T	1997	18	193	Macromol rap Com	HCA
Christ, T	1997	1		Thin Solid Films in	
Era, M	1991	78	488	Chem Phys Lett	
Gailberger, M	1991	44	8643	Phys Rev B	HCA
Hosokawa, C	1992	61	2503	Appl Phys Lett	HCA
Kido, J	1992	61	761	Appl Phys Lett	HCA
Langmuir, J	1939	170	15	Proc r Soc London, S	
Pommerehne, J	1996	7	551	Adv Mater	
Sander, R	1996	29	7705	Macromolecules	HCA
Simmerer, J	1996	8	815	Adv Mater	HCA
Tang, C	1987	51	913	Appl Phys Lett	HCA
Tokushisa, H	1996		162	Myazaki Int Symp, Ko	
Vestweber, H	1992	4	661	Adv Mater	HCA
Vestweber, H	1994	64	141	Synth Met	HCA
Wu, A	1994		2319	Chem Lett	HCA
OS.CITING REF COUNT:	78	THEF	RE ARE 7	8 CAPLUS RECORDS THAT	CITE THIS
		RECO)RD (78	CITINGS)	

L66 ANSWER 26 OF 31 HCA COPYRIGHT 2011 ACS on STN ACCESSION NUMBER: 126:284923 HCA Full-text

ORIGINAL REFERENCE NO.: 126:55035a,55038a

TITLE: Photoluminescence and electroluminescence of the blue

emission of devices based on poly(p-Phenylenevinylene)

copolymers

AUTHOR(S): Ma, Dong-ge; Hong, Zhi-yong; Zhao, Xiao-jiang; Jing,

Xia-bin; Wang, Fo-song; Shi, Jia-wei; Liu, Ming-da;

Jin, En-shun; Li, Shu-wen

CORPORATE SOURCE: Changchun Inst. of Applied Chem., Chinese Academy of

Sciences, Changchun, 130022, Peop. Rep. China

SOURCE: Chinese Physics Letters (1996), 13(12),

940-943

CODEN: CPLEEU; ISSN: 0256-307X

PUBLISHER: Chinese Physical Society

DOCUMENT TYPE: Journal LANGUAGE: English

AB Bright blue polymer light-emitting diodes have been fabricated by using the poly(p-phenylenevinylene)-based copolymers with 10 C long aliphatic chains as the electroluminescent layers, PBD in PMMA and 8-hydroxyquinone aluminum (Alq3) as the electron-transporting layers, and aluminum as the cathode. The multilayer structure devices show 190 cd/m2 light-emitting brightness at 460 nm, 15 V turn-on voltage. It is found that the intensities of photoluminescence and electroluminescence (EL) increase with increasing aliphatic chain length, the EL intensity and operation stability of these polymer light-emitting diodes can be improved by reasonable design of the structure.

IT 9011-14-7, PMMA

(hole-blocking layer; photoluminescence and electroluminescence of blue emission of devices based on poly(p-Phenylenevinylene) copolymers)

RN 9011-14-7 HCA

CN 2-Propenoic acid, 2-methyl-, methyl ester, homopolymer (CA INDEX NAME)

CM 1

CRN 80-62-6 CMF C5 H8 O2

CC 73-11 (Optical, Electron, and Mass Spectroscopy and Other Related Properties)

Section cross-reference(s): 38

IT 9011-14-7, PMMA

(hole-blocking layer; photoluminescence and electroluminescence of blue emission of devices based on poly(p-Phenylenevinylene) copolymers)

OS.CITING REF COUNT: 4 THERE ARE 4 CAPLUS RECORDS THAT CITE THIS RECORD (4 CITINGS)

L66 ANSWER 27 OF 31 HCA COPYRIGHT 2011 ACS on STN ACCESSION NUMBER: 126:278090 HCA Full-text

ORIGINAL REFERENCE NO.: 126:53919a,53922a

TITLE: New CF3-substituted PPV-type oligomers and polymers

for use as hole blocking layers in LEDs

AUTHOR(S): Lux, A.; Holmes, A. B.; Cervini, R.; Davies, J. E.;

Moratti, S. C.; Gruener, J.; Cacialli, F.; Friend, R.

Η.

CORPORATE SOURCE: Department of Chemistry, University Chemical

Laboratory, University of Cambridge, Cambridge, CB2

1EW, UK

SOURCE: Synthetic Metals (1997), 84(1-3), 293-294

CODEN: SYMEDZ; ISSN: 0379-6779

PUBLISHER: Elsevier

DOCUMENT TYPE: Journal LANGUAGE: English

AB New CF3-substituted poly(p-phenylenevinylene) derivs. were synthesized by Wittig-Horner polycondensation. To obtain a better understanding of the relationship between absorption and luminescence properties and structure a single crystal x-ray anal. of a model oligomer was performed. The effect of electron withdrawing trifluoromethyl groups at vinylidene linkages in PPVs on absorption, luminescence, hole blocking and electron injecting properties was investigated.

IT 188997-75-3P 188997-78-6P

(preparation and properties of trifluoromethyl-substituted poly(p-phenylenevinylene) derivs. synthesized by Wittig-Horner polycondensation for use as hole blocking layers in light emitting diodes)

RN 188997-75-3 HCA

CN Phosphonic acid, [[2,5-bis(octyloxy)-1,4-phenylene]bis(methylene)]bis-, tetraethyl ester, polymer with 1,1'-(1,4-phenylene)bis[2,2,2-trifluoroethanone] (9CI) (CA INDEX NAME)

CM 1

CRN 176856-31-8 CMF C32 H60 O8 P2

CM 2

CRN 86988-48-9 CMF C10 H4 F6 O2

RN 188997-78-6 HCA

CN Phosphonic acid, [[2,5-bis(octyloxy)-1,4-phenylene]bis(methylene)]bis-, tetraethyl ester, polymer with 1,1'-[1,6-hexanediylbis(oxy-4,1-phenylene)]bis[2,2,2-trifluoroethanone] (9CI) (CA INDEX NAME)

CM 1

CRN 188997-77-5 CMF C22 H20 F6 O4

CM 2

CRN 176856-31-8 CMF C32 H60 O8 P2

IT 434-45-7 4546-04-7, p-Xylylenebis(diethyl phosphonate)
(reactant; preparation and properties of trifluoromethyl-substituted poly(p-phenylenevinylene) derivs. synthesized by Wittig-Horner polycondensation for use as hole blocking layers in light emitting diodes)

RN 434-45-7 HCA

CN Ethanone, 2,2,2-trifluoro-1-phenyl- (CA INDEX NAME)

RN 4546-04-7 HCA

CN Phosphonic acid, P,P'-[1,4-phenylenebis(methylene)]bis-, P,P,P',P'-tetraethyl ester (CA INDEX NAME)

$$\begin{array}{c} \text{OEt} \\ \text{OEt} \\ \text{Eto-P-CH2} \end{array}$$

CC 37-3 (Plastics Manufacture and Processing)

IT 188997-75-3P 188997-76-4P 188997-78-6P 188997-79-7P (preparation and properties of trifluoromethyl-substituted poly(p-phenylenevinylene) derivs. synthesized by Wittig-Horner polycondensation for use as hole blocking layers in light emitting diodes)

IT 434-45-7 4546-04-7, p-Xylylenebis (diethyl phosphonate)

(reactant; preparation and properties of trifluoromethyl-substituted poly(p-phenylenevinylene) derivs. synthesized by Wittig-Horner polycondensation for use as hole blocking layers in

light emitting diodes)

OS.CITING REF COUNT: 52 THERE ARE 52 CAPLUS RECORDS THAT CITE THIS RECORD (52 CITINGS)

L66 ANSWER 28 OF 31 HCA COPYRIGHT 2011 ACS on STN ACCESSION NUMBER: 122:147285 HCA <u>Full-text</u>

ORIGINAL REFERENCE NO.: 122:27075a,27078a

TITLE: Structurally simplified electrophotographic imaging

member

INVENTOR(S):

PATENT ASSIGNEE(S):

SOURCE:

Yu, Robert C. U.

Xerox Corp., USA

U.S., 14 pp.

CODEN: USXXAM

DOCUMENT TYPE: Patent LANGUAGE: English

FAMILY ACC. NUM. COUNT: 1

PATENT INFORMATION:

PR'

PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
US 5378566	А	19950103	US 1992-970459	19921102 <
RIORITY APPLN. INFO.:			US 1992-970459	19921102 <

ASSIGNMENT HISTORY FOR US PATENT AVAILABLE IN LSUS DISPLAY FORMAT

AB An electrophotog. imaging member including a substrate, a hole blocking adhesive layer, a charge generating layer and a charge transport layer, the hole blocking adhesive layer including a polyester film forming binder having dispersed therein a particulate reaction product of metal oxide particles and a hydrolyzed reactant selected from the group consisting of a N containing organo silane, an organotitanate and an organozirconate and mixts. thereof. Preferably, the electrophotog. imaging member is free of any distinct adhesive layer in contiguous contact with the hole. blocking adhesive layer. This imaging member may be used in an electrophotog. imaging process.

IT 24936-68-3, Makrolon 5705, uses 25038-59-9, Melinex 442,

uses

(electrophotog. photoconductor with hole blocking layer from polyester dispersed coupling agent)

RN 24936-68-3 HCA

CN Poly[oxycarbonyloxy-1,4-phenylene(1-methylethylidene)-1,4-phenylene] (CA INDEX NAME)

RN 25038-59-9 HCA

CN Poly(oxy-1,2-ethanediyloxycarbonyl-1,4-phenylenecarbonyl) (CA INDEX NAME)

INCL 430058000

IPCI G03G0005-14 [ICM, 6]

IPCR G03G0005-14 [I,C*]; G03G0005-14 [I,A]

NCL 430/058.050; 430/064.000; 430/908.000

CC 74-3 (Radiation Chemistry, Photochemistry, and Photographic and Other Reprographic Processes)

IT 919-30-2 7631-86-9D, Silica, (3-aminopropyl)trimethylsilane-modified 24936-68-3, Makrolon 5705, uses 24938-04-3 25038-59-9,

Melinex 442, uses 161445-56-3, Aerosil S 506

(electrophotog. photoconductor with hole blocking

layer from polyester dispersed coupling agent)

RETABLE

Referenced Author (RAU)	Year (RPY)	VOL PG (RVL) (RPG)	Referenced Work (RWK)	Referenced
	=+====+	-===+=====	-+	====+=======
Anon		1	US 4464450 A	HCA
Anon	1 1	1	US 4654284 A	HCA
Anon	1 1	1	US 4664995 A	HCA
Anon		1	US 4786570 A	HCA
Anon	1 1	1	US 4869988 A	HCA
Anon	1 1	1	US 4946754 A	HCA
Anon	1 1	1	US 5008169 A	HCA
OS.CITING REF COUNT:	12		12 CAPLUS RECORDS CITINGS)	THAT CITE THIS

L66 ANSWER 29 OF 31 HCA COPYRIGHT 2011 ACS on STN ACCESSION NUMBER: 99:6675 HCA Full-text

ORIGINAL REFERENCE NO.: 99:1193a,1196a

TITLE: Paving and floor block composition
INVENTOR(S): Bunner, Matthew R.; Heinhuis, William H.
PATENT ASSIGNEE(S): Industrial Wood Products, Inc., USA

SOURCE: U.S., 7 pp. CODEN: USXXAM

DOCUMENT TYPE: Patent LANGUAGE: English

FAMILY ACC. NUM. COUNT: 1

PATENT INFORMATION:

PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
US 4381328	A	19830426	US 1981-301221	19810911 <
PRIORITY APPLN. INFO.:			US 1981-301221	19810911 <

ASSIGNMENT HISTORY FOR US PATENT AVAILABLE IN LSUS DISPLAY FORMAT

AB A composition and method is provided for forming paving and floor blocks which comprises forming a mixture of wood particles, phenolic resin, and paraffin wax for mold release properties and molding the composition into blocks containing a plurality of holes on the underside. Thus, wood particles (14-20 mesh) 88.5, formaldehyde-phenol copolymer [9003-35-4] 9.5, and paraffin wax 2.0% were mixed and molded at 320°F at 400 psi into a block having holes on

the underside extending to within $\geq 1/2$ in. of the top surface and ≥ 0.4 in.

INCL 428171000

IPCI B32B0003-26 [ICM]; B32B0005-16 [ICS] IPCR B27N0005-00 [I,C*]; B27N0005-02 [I,A]

NCL 428/171.000; 428/170.000; 428/218.000; 428/326.000; 428/332.000;

428/485.000

38-3 (Plastics Fabrication and Uses)

Section cross-reference(s): 43

Referenced Author | Year | VOL | PG | Referenced Work | Referenced | File $(RAU) \qquad |(RPY)|(RVL)|(RPG)| \qquad (RWK)$ Anon

L66 ANSWER 30 OF 31 HCA COPYRIGHT 2011 ACS on STN ACCESSION NUMBER: 84:18679 HCA Full-text

ORIGINAL REFERENCE NO.: 84:3101a,3104a

TITLE: Continuous production of propylene oxide

Yamaqishi, Kazuo; Kaqeyama, Osamu; Numa, Sadaaki

INVENTOR(S):

PATENT ASSIGNEE(S):

Daicel Ltd., Japan

Jpn. Tokkyo Koho, 6 pp.

CODEN: JAXXAD

DOCUMENT TYPE: Patent LANGUAGE: Japanese

FAMILY ACC. NUM. COUNT: 1

PATENT INFORMATION:

PATENT NO. KIND DATE APPLICATION NO.

JP 50024284 B 19750814 JP 1974-79416 _____ B 19750814 JP 1974-79416 19740711 <--JP 1974-79416 A 19740711 <--PRIORITY APPLN. INFO.: AB A tubular reactor is described for the continuous preparation of propylene oxide [75-56-9] from propylene (I) [115-07-1] and peracetic acid (II) [79-21-0]. The reactor has continuous reaction zones defined by blocking plates having holes of 2-10 mm diameter, the total area of the holes being 1-20%. A solution of II in an organic solvent was fed into the reaction zones from one end, and at the same time, I was introduced such that the I partial pressure was ≥3 kg/cm2, thereby forming I bubbles which agitate the reaction solution in each zone. The product was removed from the opposite end of the reactor. IPCI C07D0301-14; C07D0301-00[C*]; C07D0303-04; C07D0303-00 [C*] IPCR C07D0301-00 [I,C*]; C07D0301-14 [I,A]; C07D0303-00 [I,C*]; C07D0303-04 [I,A]

CC 37-2 (Plastics Fabrication and Uses) Section cross-reference(s): 27

L66 ANSWER 31 OF 31 HCA COPYRIGHT 2011 ACS on STN ACCESSION NUMBER: 77:76265 HCA Full-text

ORIGINAL REFERENCE NO.: 77:12585a,12588a

TITLE: INVENTOR(S): Compositions for securing fixing elements

Murphy, John Michael

Explosives and Chemical Products Ltd. PATENT ASSIGNEE(S):

Brit., 5 pp. SOURCE: CODEN: BRXXAA

DOCUMENT TYPE: Patent English

FAMILY ACC. NUM. COUNT: 1

PATENT INFORMATION:

PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
GB 1277425		19720614	GB 1968-52703	19681106 <-

AB A styrene [100-42-5] -containing Leguval K25R (I) [12688-27-6] polyester resin sheet cured with a filler-containing benzoyl peroxide [94-36-0] formed a hand-kneadable composite used for securing and anchoring bolts in concrete constructions. For example, a polyester sheet layer containing I, diisooctyl maleate(II), dolomite dust, asbestos fiber, and Aerosil silica was contacted with a sheet containing B200H, II, dolomite dust, asbestos fiber, and Aerosil silica. This composite was hand-kneaded until homogeneous, rolled into cylindrical shape, and placed in drilled concrete block holes. The bolt was inserted into the composite, and after 12 min, a load of 1500-1800 lb was required to remove the bolt. IPCI C08F

IPCR B32B0015-08 [I,C*]; B32B0015-08 [I,A]; C08F0283-00 [I,C*]; C08F0283-01
 [I,A]

CC 37-3 (Plastics Fabrication and Uses)